

ANALYSIS OF VDDDA BASED VOLTAGE-MODE MISO AND SIMO UNIVERSAL FILTER

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Submitted by:

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CANDIDATE'S DECLARATION

I, DHRUV GOEL, Roll No. 2K18/VLS/02 student of MTech (VLSI Design and Embedded System), hereby declare that the project titled “**Analysis of VDDDA based Voltage-Mode MISO and SIMO Universal Filter**” which is submitted by me to the Department of Electronics And Communication Engineering, Delhi Technological University, Delhi in partial fulfilment of the requirement for the award of the degree of Master of Technology, is original and not copied from any source without proper citation. This work has not previously formed the basis for the award of any Degree, Diploma Associate ship, Fellowship or other similar title or recognition.



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CERTIFICATE

I hereby certify that the Project Dissertation titled “**Analysis of VDDDA based Voltage-Mode MISO and SIMO Universal Filter**” which is submitted by DHRUV GOEL, Roll No. 2K18/VLS/02, Electronics and Communication Engineering, Delhi Technological University, Delhi in partial fulfilment of the requirement for the award of the degree of Master of Technology, is a record of the project work carried out by the student under my supervision. To the best of my knowledge this work has not been submitted in part or full for any Degree or Diploma to this University or elsewhere.

Place: Delhi
Date: 31/08/2020

**Dr. DEVANAND
SUPERVISOR**

To My Parents,
Mrs. Asha Goel & Mr. Shiv Kumar Goel
And
All My Teachers

ACKNOWLEDGEMENT

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ABSTRACT

Research on analog signal processing has been heavily explored in the analysis and applications of various active building blocks (ABBs), which are expected to perform better than traditional op amps. Voltage Differencing Differential Difference Amplifier (VDDDA) is one such new versatile ‘voltage differencing’ active building block (ABB). It is a universal block to realize various amplifiers with less transistor count. Device’s internal structure consists of operational transconductance amplifier (OTA) followed by differential difference amplifier (DDA).

In this project, two second order voltage-mode filters are proposed using the VDDDA as an active block. The first proposed filter is sort of MISO multifunction filter having three input nodes and single output node. It consists of one VDDDA, one resistor and two identical capacitors. The proposed filter can provide five standard functions: Low-Pass (LP), High-Pass (HP), Band-Pass (BP), Band-Stop (BS) and All-Pass (AP) responses for the same circuit topology. The natural frequency and quality factor both can be electronically controllable and tuneable.

The second proposed filter is universal voltage-mode SIMO filter. It comprises of three VDDDAs, two grounded capacitors and single grounded resistor. The input voltage node exhibits high impedance. The proposed filter simultaneously provides Low-Pass (LP), High-Pass (HP), Band-Pass (BP), Band-Reject (BR) and All-Pass (AP) responses with same circuit topology. The natural frequency and quality factor can be tuned electronically and orthogonally by dc bias current. The impedance at output nodes HP, AP and BR has low impedance which can connect to other circuit without the use of voltage buffer. This makes the proposed filter suitable for IC development.

The theoretical results are verified by SYMICA DE simulations using TSMC 0.18 μ m SCN018 CMOS process parameters with ± 0.9 V supply voltages.

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CHAPTER 1

INTRODUCTION

1.1 Background

The demand for analog and digital circuits with extremely low supply voltages and low power consumption has become a topic of great significance for long term prospects which influence the improvement of microelectronic industry [1]. In numerous applications, extra necessities show up, especially the extraordinary speed or the accuracy of signal processing. There is a problem in meeting the above requirements at the same time and the trade-off arrangements ought to be utilized in real time applications [2].

Over the last 20 years, the evolution of modern analog signal processing applications has followed the trend of so-called current-modes [3], where the signal representing the information being processed is in the form of a current. In contrast to traditional voltage- mode, which utilizes voltage, current-mode circuits can exhibit, among other things, higher bandwidth and better signal linearity under certain conditions. They are designed for low voltage swings, so smaller supply voltages can be used. Simultaneously with the development of current-mode applications, mixed mode circuits are also analyzed because the interface between sub-blocks operating in different modes needs to be optimized. There is even another justification for mixed-mode operation and return to traditional voltage-mode. Some generally accepted statements about the benefits of current-mode [4] seem to have no real rationale.

Voltage Differencing Differential Difference Amplifier (VDDDA) [5] is a new versatile ‘voltage differencing’ active building block (ABB). It is a six-terminal universal block to realize various amplifiers with less transistor count and constitute dynamic properties required for any real-time applications. Device’s internal structure consists of operational transconductance amplifier (OTA) followed by differential difference amplifier (DDA). This building block consists of three addition/subtraction input voltage terminals where the transconductance (g_m) of the block can be tuned electronically. In analog signal processing, we use VDDDA as an active building block which offers various advance features, for example,

electronic controllability, avoiding the need of external voltage summing circuit in circuit design, quick circuit synthesization with least number of external passive components, etc. Especially, in the design of voltage-mode active filter which is an important requirement for application in electrical and electronic system [1], the voltage summing is required in filter thus; VDDDA is a good choice for designers. Moreover, the output impedance of VDDDA is low which allows the cascability of devices without the need of voltage buffer.

The universal filters are considered as the versatile circuit because they can offer multiple filter response in the same circuit without altering the circuit topology. If we consider the input and output terminals as a parameter, there are four types of universal filter. The first one is simple and not being used frequently i.e., single input single output (SISO) filter. The second one is single input multiple outputs (SIMO) filter. This filter topology simultaneously provides several output responses. The third filter is called as the multiple inputs multiple outputs (MIMO) universal filter. The last one is the multiple inputs single output (MISO) filter. In this MISO filter, there is only single output port, but we can select multiple output filter responses by applying the suitable input signal. The attractive way to select the input signal to obtain the desired output response is to use the digital switch which is easy to control by microcontrollers. Therefore, in this project report, we have proposed one MISO multifunction filter and one SIMO universal filter using VDDDA block.

1.2 Current-mode and Voltage-mode signal processing

The signal processing performed on electrical or electronic circuits is carried out through organized charge motion, where currents and voltages are usually variables and time, resistance, inductance and capacitance are the circuit parameters that define the characteristics of signal processing. The reason for the use of voltage and current in analog signal processing is that the active devices used in analog electronics primarily use resistance (conductance) as the parameters for control signal processing. The signal is then processed through a variety of voltage-current and current-voltage conversion, amplification, weighted addition, and multiplication. In the past, voltage was used as the primary variable for signal processing because designers thought voltage processing was easier and simpler than current. In the early

years of analog electronics, only voltage mode processing was practical, and most of the building blocks used in analog electronics, such as op amps, were typical voltage processing circuits.

Over the time, for analog signal processing there is need to increase the speed of circuits and also to reduce the supply voltages of integrated circuits and so what the designers do, they began to dedicate themselves to the so-called current mode. In current mode, the individual circuit elements should be controlled by current and not by voltage.

There is a difference one can study between voltage and current mode circuits is that a single output terminal of a current processing block is able to supply only a single input terminal, because it is not possible to arrange the inputs of the current processing blocks into a serial connection [4]. Therefore, to supply the same input signal to multiple input terminals of the block, it is necessary to design current processing building blocks with multiple outputs giving the same output signal while in voltage processing circuits a single voltage-output terminal can supply more voltage-input terminals connected in parallel. .

As more and more advances in the field of analog system and circuits were made, need for some application specific modes also aroused. In certain circuits, the input was current and the output was needed to be voltage, these circuits were called trans-impedance mode circuits. Similarly, in some other circuits the input was voltage and the output was needed as current, such circuits are called trans-admittance mode circuits. These modes are however very application specific.

1.3 Analog Filter Design

Basically, Digital circuits can operate only with two voltage values, while analog circuits can process the signals with continuous variation of voltages. But we know the fact that no macroscopic signal can truly quantized, so the digital circuit designers must have some familiarity or knowledge of analog electronics also to work with signals. Therefore, analog circuit design plays a pivotal role in the today's integrated circuit technology. The most common used analog electronic circuits are filters, active filters, oscillators, active oscillators, multi-vibrators, rectifiers, mixers, etc. A simple analog filters or passive filters consist of either

all three or any two out of resistors, capacitors and inductors. And accordingly, we have, RC, RL, LC and RLC circuits. Using these passive circuits, a filter can be designed by blocking certain frequencies and passing another signal frequency [1].

The active filters are those filters which uses active components like amplifiers in their circuit along with some passive elements. Inclusion of active components, like amplifiers, it improves the performance and expectedness of a filter, while the requirement for inductors is also avoided as inductors are typically expensive and bulky. An amplifier inhibits the load impedance of the succeeding stage from upsetting the characteristics of the filter. But on the other hand, active devices also bring some limitations to the circuits like finite bandwidth, noise injection, and more power consumption into the circuit, etc.

Filters are analog electronic circuits that process signals depending on the frequency. The fundamental filter concept can be explained by examining the frequency dependence of the impedance of the inductor and capacitor. Consider a voltage divider whose shunt leg has a reactive impedance. As the frequency changes, the reactive impedance value and the voltage division ratio changes. This mechanism is called as the frequency response because it causes the input/output transfer function to change in a frequency-dependent manner.

Filters are used for numerous practical purposes. A Lowpass filters are often used to roll off the gain and stabilize the amplifier at higher frequencies, as excessive phase shift can cause oscillations. High pass filters can be used to block the DC offset of high gain amplifiers or single supply circuits. Filter circuits are commonly used to isolate or separate signals, pass signals of interest, and attenuate the undesirable/unwanted frequencies.

A radio receiver is one such example, where the signal, with desired gain that you wanted to process is passed through the filter and the rest of the signal is attenuated. Filters are also used for data conversion, eliminating the effects of aliasing on A/D systems. They are also used to reconstruct the output signal of a digital-analog system, removing high frequency components such as the sampling frequency and its harmonics, and also unwanted noise mixed in the filtering signal to get desired waveform.

The ideal filter magnitude response has unity or some definite gain over the desired frequencies known as the pass band region and zero elsewhere known as the stop band region. Cut-off frequency is the frequency at which the filter response curve changes from passband to stopband or vice-versa depending upon the filter configuration. Fig.1 shows an ideal filter response of all filters i.e., low-pass (LP), high-pass (HP), band-pass (BP), band-reject (BR) and all-pass (AP) filters. In LP filter, passband is the region of low frequencies and stopband is the region of higher frequencies [2].

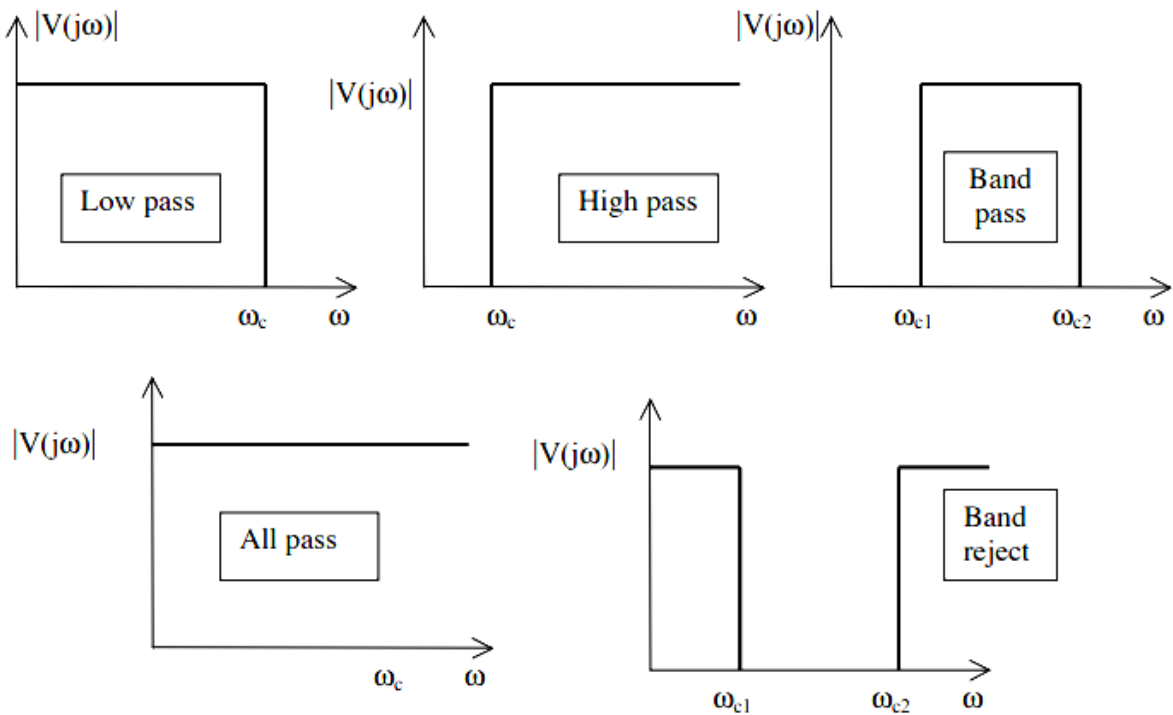


Fig. 1 Ideal responses of different filters [2]

The filter that complements the low-pass functionality is high-pass filter. Here, the passband allows high range of frequencies and stopband has low range of frequencies. A band-pass filter is created by cascading two filters i.e., HP and LP filter. The band-pass filter passes the range of frequencies i.e., a frequency band between a lower cut-off frequency, ω_{c1} and an upper cut-off frequency, ω_{c2} . Frequencies below ω_{c1} and above ω_{c2} come under the region of stopband.

Band-pass filter is the function that complements the band-reject, or notch filter. Here, the pass bands include frequencies below ω_{c1} and above ω_{c2} . The frequency band from ω_{c1} to ω_{c2} fall under the stopband region. The all-pass filter has constant amplitude, so it passes all frequencies equally, as shown in Fig.1. If it is desired to shift the phase as needed without changing the magnitude portion of the frequency response, it is usually placed in a cascade. Unfortunately, the ideal filter defined above is not easy to build. There is a transition region from pass band to stop band in all-pass filter rather not instantaneous transition. Stop band attenuation is not infinite.

Standard Biquadratic Filters or Biquads

The transfer function for the second-order filter is in the form of,

$$H(s) = \frac{N(s)}{D(s)} = \frac{b_2s^2 + b_1s + b_0}{s^2 + a_1s + a_0} \quad (1)$$

is called as biquadratic function. The problem here is that if the poles and zeros of the filtering function lie on the negative real x-axis then those poles and zeros can be realized using a passive RC network [2]. For those cases, we can define the transfer function as

$$H(s) = \frac{N(s)}{D(s)} = H_0 \frac{s^2 + (\omega_z/Q_z)s + \omega_z^2}{s^2 + (\omega_p/Q_p)s + \omega_p^2} \quad (2)$$

“where, H_0 is the maximum gain or midband frequency gain which could be positive or negative. Here, ω_p and Q_p are the pole-frequency and pole Q-factor respectively; sometimes ω_p is also known as undamped natural frequency or cut-off frequency since there will be resonance at $s = j\omega_p$ in Eq. (2).” [2]

Table 1 Biquads transfer functions [9]

Types of filter	N(s)
Low pass	$H_0\omega_0^2$
High pass	H_0s^2
Band pass	$H_0(\omega_0/Q_0)s$
All pass	$H_0(s^2 - (\omega_0/Q_0)s + \omega_0^2)$
Band reject / Notch	$H_0(s^2 + \omega_0^2)$

Note: For all filters,

$$H(s) = \frac{N(s)}{D(s)}, \text{ with } D(s) = s^2 + (\omega_0/Q_0)s + \omega_0^2$$

From table 1, it is observed that by selecting the appropriate values of the coefficients b_0 , b_1 and b_2 , we can get various types of biquads transfer functions.

1.4 Motivation

The VDDDA based circuits for analog signal processing can be found in the literature surveys where many applications are designed such as first-order voltage-mode filter, inductance simulator, oscillator, SIMO & MISO voltage-mode multifunction biquad filter, etc. In general, following are the desired features of VDDDA, which motivates one to use this building block for the filter designing:

- 1) It can provide inverting as well as non-inverting voltage-mode outputs simultaneously from the same circuit topology.
- 2) Voltage input terminals are of high impedance and voltage-mode output terminals are of low impedance, thus easing the device cascadability.
- 3) Use of grounded passive elements in filter circuit is advantageous for monolithic integration.

- 4) It consists of three addition/subtraction input voltage terminals where the transconductance (g_m) of the block can be tuned electronically.
- 5) Realization of different filter transfer function for proposed MISO and SIMO filter with same circuit topology depending upon the terminals used.

1.5 Objective

The main objective of this report is to describe the proposed design of second-order multifunction voltage-mode filter using VDDDA as an active building block. The proposed MISO and SIMO filters provide all five filtering functions namely, low-pass, high-pass, band-pass, band-reject and all-pass responses for the same circuit configuration. Also, the natural frequency and the Q-factor of filter can be electronically tuneable and controllable.

1.6 Organization of Report

This report has been organized into five chapters. In Chapter 1, it starts with the introduction of analog filter design and its standard filter equations. It also includes the motivation and objective behind the report. Chapter 2 deals with the literature study of various voltage- mode MISO and SIMO filters. Chapter 3 deals with the description of circuit design of VDDDA block and detailed analysis of the proposed MISO filter and SIMO filter. In chapter 4, all the simulation results with schematic and waveforms of the proposed filter are presented. Chapter 5 deals with the conclusion and future scope of the proposed filter.

CHAPTER 2

LITERATURE REVIEW

Despite the significant development in digital signal processing and its real time applications, one can never replace the analog signal processing due to its particular advantages. Amplification, rectification, modulation, etc, processed on the message signals can only be performed by the analog processing. Various devices that can process the analog electrical signals have been designed and further modifications in circuits are done according to their characteristics. These modified devices could now further be used for applications such as amplifiers, summers, filters, oscillators, wave generators etc. One of the key applications of analog signal processing is electronic filter. A filter can be designed by allowing the electrical signals of certain frequencies to pass through it depending upon their type and blocking the unwanted or undesired frequencies, which can be “low pass” , “high pass” , “band pass” , “band reject” and “all pass” filter. “Current-mode”, “voltage-mode”, “trans-conductance-mode” and “trans-resistance-mode filters” are various available modes of the filter operation [9]. Multifunction filter is the one that is capable of performing two or more types of filtering functions whereas universal filter is the one that can perform all five types of filtering functions. Further according to number of input and output terminals, filters are classified into four types which are “Single-Input-Single-Output” (SISO), “Single-Input-Multiple-Output” (SIMO), “Multiple-Input-Single-Output” (MISO) or “Multiple-Input-Multiple-Output” (MIMO) type.

2.1 Comparison of various voltage-modes SIMO filters

Many literature surveys have been conducted for voltage-mode universal filters using active building block. A comparison has been done between the proposed SIMO filter and the other referenced VM SIMO filter as shown in Table 2. This table tabulates the advantages and disadvantages of the previously filters as well as the proposed filter. From the table it is noted that for second-order filtering function; we require at least two capacitors for quadratic equation. Filters in [21, 22, 24, 27, 31, 33, 35, 36, 39, 40, and 43] consist of floating passive elements in their circuit. Electronic tunability between natural frequency (ω_0) and Q-factor (Q_0)

can be achieved in filters [25, 26, 28-32, 36-39, 41, and 42]. All standard five filter responses can't be realized in these filters: [23, 25-27, 29, 31, 34, 35, 37-40, and 42].

Table 2 Comparison of different VM SIMO filters

Refs.	ABB	No. of ABB	No. of R+C	All grounded passive elements	Electronic Tune	Orthogonal tune of Q and ω_0	High input impedance	Low output impedance	Five filter responses	Technology
20	DVCC	3	3+2	Yes	No	No	Yes	No	Yes	CMOS
21	DVCC	3	3+2	No	No	Yes	Yes	No	Yes	CMOS
22	DVCC	2	3+2	No	No	Yes	No	No	Yes	CMOS
23	FDCCII	1	2+2	Yes	No	No	Yes	No	No	CMOS
24	DDCC	3	2+2	No	No	No	No	No	Yes	CMOS
25	DDCC & OTA	2	1+2	Yes	Yes	No	Yes	No	No	CMOS
26	OTA	8	0+2	Yes	Yes	Yes	Yes	No	No	CMOS
27	CFOA	1	3+2	No	No	Yes	No	LP	No	Commercial IC
28	DDCCTA	2	2+2	Yes	Yes	No	Yes	No	Yes	CMOS
29	OTA	8	0+2	Yes	Yes	Yes	Yes	No	No	CMOS
30	DDCCTA	3	0+2	Yes	Yes	No	Yes	AP	Yes	CMOS
31	CCCCTA	1	1+3	No	Yes	Yes	No	No	No	BJT
32	DDCCTA	2	2+2	Yes	Yes	No	Yes	AP	Yes	CMOS
33	FDCCII	1	3+2	No	No	No	No	No	Yes	CMOS
34	DVCC	4	5+2	Yes	No	Yes	Yes	No	No	CMOS
35	DVCC	2	2+3	No	No	No	No	No	No	CMOS
36	DDCCTA	2	2+2	No	Yes	Yes	Yes	No	Yes	CMOS
37	VD-DIBA	2	0+2	Yes	Yes	No	Yes	HP	No	Commercial IC
38	VDCC	1	2+2	Yes	Yes	Yes	No	No	No	CMOS
39	VDCC	1	2+2	No	Yes	Yes	No	No	No	BJT
40	CCII	2	3+2	No	No	No	Yes	No	No	CMOS
41	DDCCTA	2	3+2	Yes	Yes	Yes	Yes	AP	Yes	CMOS
42	VDTA	1	0+2	Yes	Yes	No	Yes	No	No	CMOS
43	CCII	4	5+2	No	No	Yes	Yes	No	Yes	Commercial IC
This work	VDDDA	3	1+2	Yes	Yes	Yes	Yes	HP,AP,BS	Yes	CMOS

Those circuits that can't provide high input impedance are [22, 24, 27, 31, 33, 35, 38, and 39]. The proposed SIMO filter can provide low output impedance for HP, BS and AP filter. The natural frequency and Q-factor can be orthogonally tuneable in filters [21, 22, 26, 27, 29, 31, 34, 36, 38, 39, 41, and 43]. The circuits which have commercialised IC are [27, 37, and 43].

2.2 Comparison of various voltage-mode MISO filters

Many literature surveys have been conducted and numerous designing techniques have been developed for voltage-mode universal filters using active building block. A comparison has been done between the proposed MISO filter and the other referenced voltage-mode MISO filter as shown in Table 3. This table tabulates the advantages and disadvantages of the previously filters as well as the proposed filter.

From the table 3, it is noted that for second-order filtering function; we require at least two capacitors for a quadratic equation. Filters in [44-46, 48, 50, 52, 53, 56-58] consist of floating passive elements in their circuit. Electronic tunability between natural frequency (ω_0) and Q-factor (Q_0) can be achieved in filters [46, 48, 51-53, 55, 57-59]. All standard five filter responses can be realized in all surveyed filters. Those circuits that can't provide high input impedance are [45, 47, 48, 50, 52, 53, 55-58]. The filters that can provide low output impedance are [47, 49, 50, 56, and 59]. The mentioned voltage-mode MISO filters in [44, 45, 50, 53-55] require matching condition between passive elements. Also the circuits in [44-46, 48, 53, and 58] need inverting input signals for filter responses.

Table 3 Comparison of different VM MISO filters

Reference	ABB	No. of ABB	No. of R+C	All grounded passive elements	Electronic Tune	Matching condition	High input impedance	Low output impedance	Inverting input
44	CCII	3	2+2	No	No	Yes	Yes	No	Yes
45	CFA	1	3+2	No	No	Yes	No	No	Yes
46	OTA & CCII	3	0+2	No	Yes	No	Yes	No	Yes
47	DDCC	2	2+2	Yes	No	No	No	Yes	No
48	OTA	2	0+2	No	Yes	No	No	No	Yes
49	DDCC	3	2+2	Yes	No	No	Yes	Yes	No
50	OTRA	1	4+4	No	No	Yes	No	Yes	No
51	OTA	6	0+2	Yes	Yes	No	Yes	No	No
52	CCTA	1	2+2	No	Yes	No	No	No	No
53	DVCC	1	2+2	No	Yes	Yes	No	No	Yes
54	DVCC	3	4+2	Yes	No	Yes	Yes	No	No
55	VDTA	1	0+2	Yes	Yes	Yes	No	No	No
56	CDBA	2	4+2	No	No	No	No	Yes	No
57	VD-DIBA	1	1+2	No	Yes	No	No	No	No
58	VDDDA	1	2+2	No	Yes	No	No	No	Yes
59	VDDDA	2	0+2	Yes	Yes	No	Yes	Yes	No
This work	VDDDA	1	1+2	No	Yes	Yes	LP	No	Yes

CHAPTER 3

CIRCUIT DESIGN

Usually designers use the tactics of designing the electronic circuits and filters with active building block for design flexibility. The circuit realized by the active building block requires a minimum number of external passive elements which can be either grounded or floating components to get desired functionality. The VDDDA is one of such interesting active building block [5].

3.1 VDDDA (Voltage Differencing Differential Difference Amplifier)

Voltage Differencing Differential Difference Amplifier (VDDDA) is one of the new versatile ‘voltage differencing’ active building block (ABB). It is a six terminal universal block to realize various amplifiers with less transistor count and constitute dynamic properties required for any real-time applications. Device’s internal structure consists of operational transconductance amplifier (OTA) [11] followed by differential difference amplifier unit (DDA) [12], [13].

This building block consists of three addition/subtraction input voltage terminals where the transconductance (g_m) of the block can be tuned electronically. The circuit symbol and its equivalent circuit are shown in Fig. 2. It has five input voltage ports, named as V_+ , V_- , Z, P and N. The Z port is also the output current terminal and the W port is the output voltage terminal. Ideally, the input impedance at V_+ , V_- , Z, P and N ports are high and the output impedance at W port is low. The voltage difference between V_+ and V_- is transmitted as an output current I_z via the transconductance (g_m) which is tuneable too. The differential input voltages of V_z , V_n and V_p constitutes output voltage V_w .

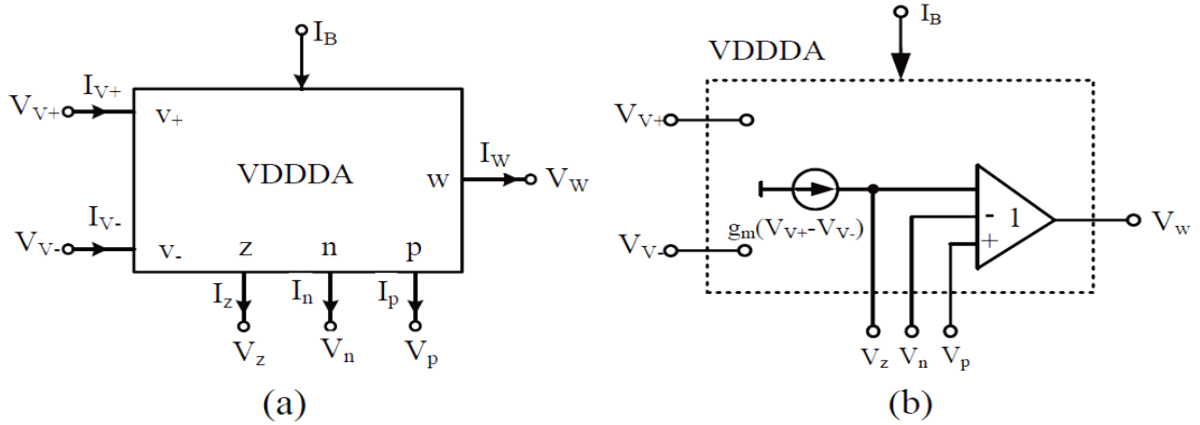


Fig. 2 (a) VDDDA Circuit Symbol, (b) its Equivalent circuit [5]

The terminal characteristic equation for an ideal VDDDA can be modelled in form of matrix equation which is as follows:

$$\begin{pmatrix} I_{v+} \\ I_{v-} \\ I_z \\ I_n \\ I_p \\ V_w \end{pmatrix} = \begin{pmatrix} 0 & 0 & 0 & 0 & 0 & 0 \\ 0 & 0 & 0 & 0 & 0 & 0 \\ g_m & -g_m & 0 & 0 & 0 & 0 \\ 0 & 0 & 0 & 0 & 0 & 0 \\ 0 & 0 & 0 & 0 & 0 & 0 \\ 0 & 0 & 1 & -1 & 1 & 0 \end{pmatrix} \begin{pmatrix} V_{v+} \\ V_{v-} \\ V_z \\ V_n \\ V_p \\ I_w \end{pmatrix} \quad (3)$$

Following are the equations derived from matrix equation,

$$I_{v+} = I_{v-} = I_n = I_p \quad (4)$$

$$I_z = g_m (V_{v+} - V_{v-}) \quad (5)$$

$$V_w = \beta_1 V_z - \beta_2 V_n + \beta_3 V_p \quad (6)$$

“where in ideal scenario, the currents at terminals v_+ , v_- , n and p are equal to zero from Eq. (4). In Eq. (5) and (6), g_m and $\beta_i = 1 - \varepsilon_{vi}$ for $i = 1, 2, 3$ and so on, represent the transconductance and the non-ideal voltage gain of VDDDA respectively, and ε_{vi} which is less than one in magnitude denotes the voltage tracking error of block VDDDA. For ideal case, β_i is taken as unity gain.” [5]

The internal structure of VDDDA is implemented through CMOS which is shown in Fig. 3, where transistors M_1 – M_4 realize the OTA unit and M_5 – M_{14} realizes the DDA unit. Note, we can utilize the same CMOS circuit structure effectively for implementation of VDBA [6] and VD-DIBA [7], if V_n and V_p or only V_p terminals of VDDDA are grounded.

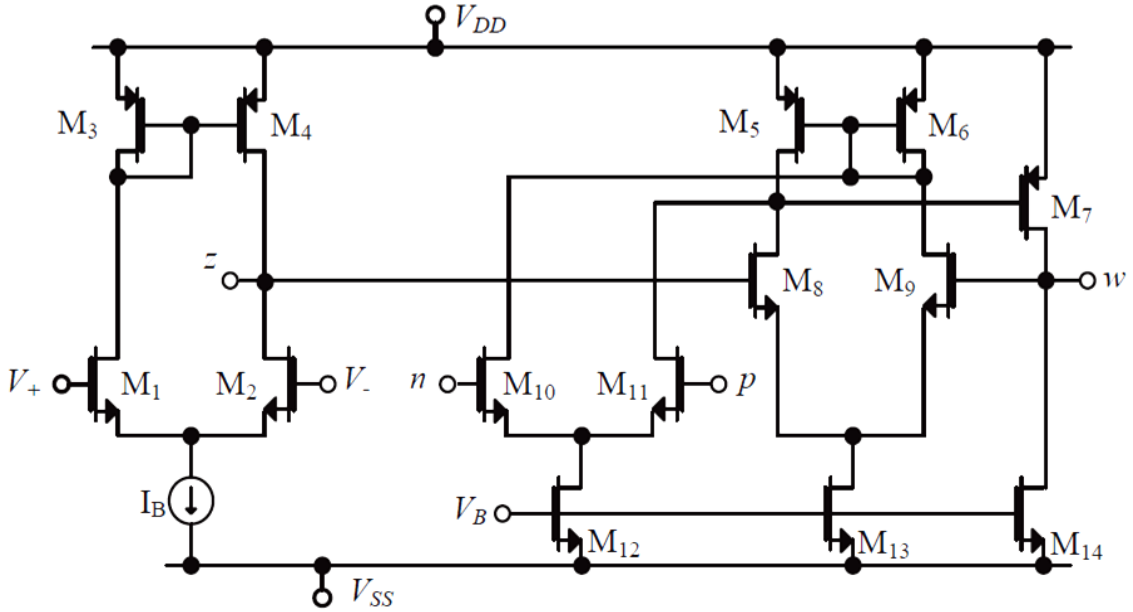


Fig. 3 VDDDA implemented by CMOS technology [3]

The transconductance, g_m of the CMOS implemented VDDDA depends on both bias current (I_B) and physical parameter of CMOS transistor, which is given by,

$$g_m = \sqrt{\mu C_{ox} \left(\frac{W}{L}\right)_{1,2} I_B} \quad (7)$$

“where, μ is the mobility of the charge carrier for NMOS transistors i.e., M_1 and M_2 transistors, C_{ox} is the gate oxide capacitance per unit area and W/L is the aspect ratio where W is channel width and L is channel length of transistor.” [8]

3.2 Proposed MISO Filter Description

Filter plays a pivotal role in analog signal processing. They are two major classifications of filter i.e., analog and digital filters. Compared to digital one, analog filters are quite faster, less expensive and have dynamic range in both frequency and amplitude. In numerous applications, analog filters are generally used such as noise reduction, graphic equalizers, videos signal enhancement for advanced systems. There are two major categories of analog filter circuits: Voltage-mode and current-mode. Voltage mode analog filter can be further classified into multi input single output (MISO) type and single input multi output (SIMO) type voltage filter. For the designing of MISO type voltage-mode universal filters in signal processing, designers are giving major importance due to following key features: (i) Realization of all standard five filter responses with same circuit topology on the basis of input ports used. (ii) Minimum use of active and passive components in circuit design (iii) Design simplicity and versatility that bring cost reduction to IC manufacturer [19].

Fig. 4 shows the proposed second order voltage-mode MISO filter. The filter consists of single VDDDA, two capacitors and one resistor. It is noted that the proposed filter uses minimum number of active elements which is an attractive feature for integration. In future study circuit can further be modified by replacing the resistor with CMOS implemented electronic resistor. In this filter design, there are three input voltage signals, namely V_{in1} , V_{in2} , V_{in3} and V_0 is the only output voltage. Considering an ideal VDDDA block, mathematical analysis of the MISO filter provides the output voltage, which is given as,

$$V_0 = \frac{s^2 V_{in3} + s \frac{(C_1 V_{in2} + C_2 R g_m V_{in3})}{2C_1 C_2 R} + \frac{g_m V_{in1}}{2C_1 C_2 R}}{D(s)} \quad (8)$$

where,

$$D(s) = s^2 + s \frac{(C_1 + C_2 R g_m)}{2C_1 C_2 R} + \frac{g_m}{2C_1 C_2 R} \quad (9)$$

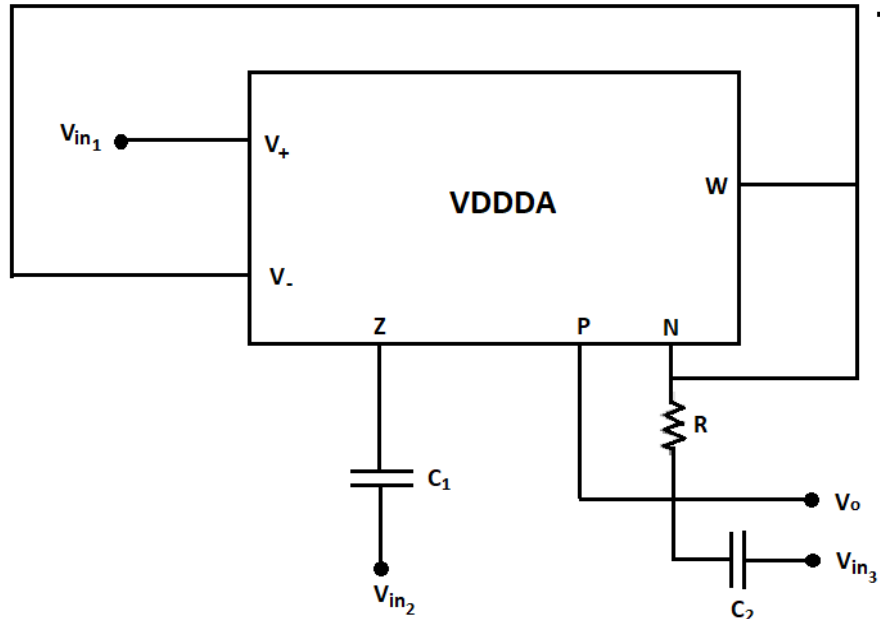


Fig. 4 VDDDA based voltage-mode MISO filter

It is found from Eq. (8) that the proposed MISO filter has unity gain and if we want to achieve desired gain from the active filter, designers need to add voltage amplifiers to get additional gain. From Eq. (8), we can get all standard five output filter responses by selecting the input voltage terminals (V_{in}) accordingly and selection can be done digitally through below conditions,

- The second order LP response can be obtained if $V_{in1} = V_{in}$ and $V_{in2} = V_{in3} = 0$.
- The second order HP response can be obtained if $-V_{in2} = V_{in3} = V_{in}$ and $V_{in1} = 0$.
- The second order BP response can be obtained if $V_{in2} = V_{in}$ and $V_{in1} = V_{in3} = 0$.
- The second order BS response can be obtained if $V_{in1} = -V_{in2} = V_{in3} = V_{in}$.
- The second order AP response can be obtained if $V_{in1} = \frac{-V_{in2}}{3} = V_{in3} = V_{in}$.

For hardware implementation of HP and BS filter response, there is need of inverting unity gain amplifier and for AP filter implementation, inverting triple gain amplifier is required. From the characteristic equation Eq. (9), we can find the natural frequency and quality factor given by:

$$\omega_0 = \sqrt{\frac{g_m}{2C_1C_2R}} \quad (10)$$

$$Q_0 = \frac{\sqrt{2C_1C_2Rg_m}}{C_1 + C_2Rg_m} \quad (11)$$

It is observed from Eqs (10) and (11) that the natural frequency (ω_0) and quality factor (Q_0) both are tuned electronically through transconductance, g_m . And, for realizing HP, BS and AP filter responses; there is need of component matching condition ($C_1 = C_2Rg_m$). The relative sensitivities of natural frequency and quality factor for the proposed filter can be calculated in Eq. (12),

$$S_{g_m}^{\omega_0} = \frac{1}{2}; \quad S_{C_1}^{\omega_0} = S_{C_2}^{\omega_0} = S_R^{\omega_0} = -\frac{1}{2};$$

$$S_{C_1}^{Q_0} = \frac{1}{2} - \frac{C_1}{C_1 + C_2Rg_m}; \quad S_{g_m}^{Q_0} = S_{C_2}^{Q_0} = S_R^{Q_0} = \frac{1}{2} - \frac{C_2Rg_m}{C_1 + C_2Rg_m} \quad (12)$$

It is observed that the magnitude of relative sensitivities is either equal to one or less than one.

3.3 Proposed high input impedance SIMO Filter Description

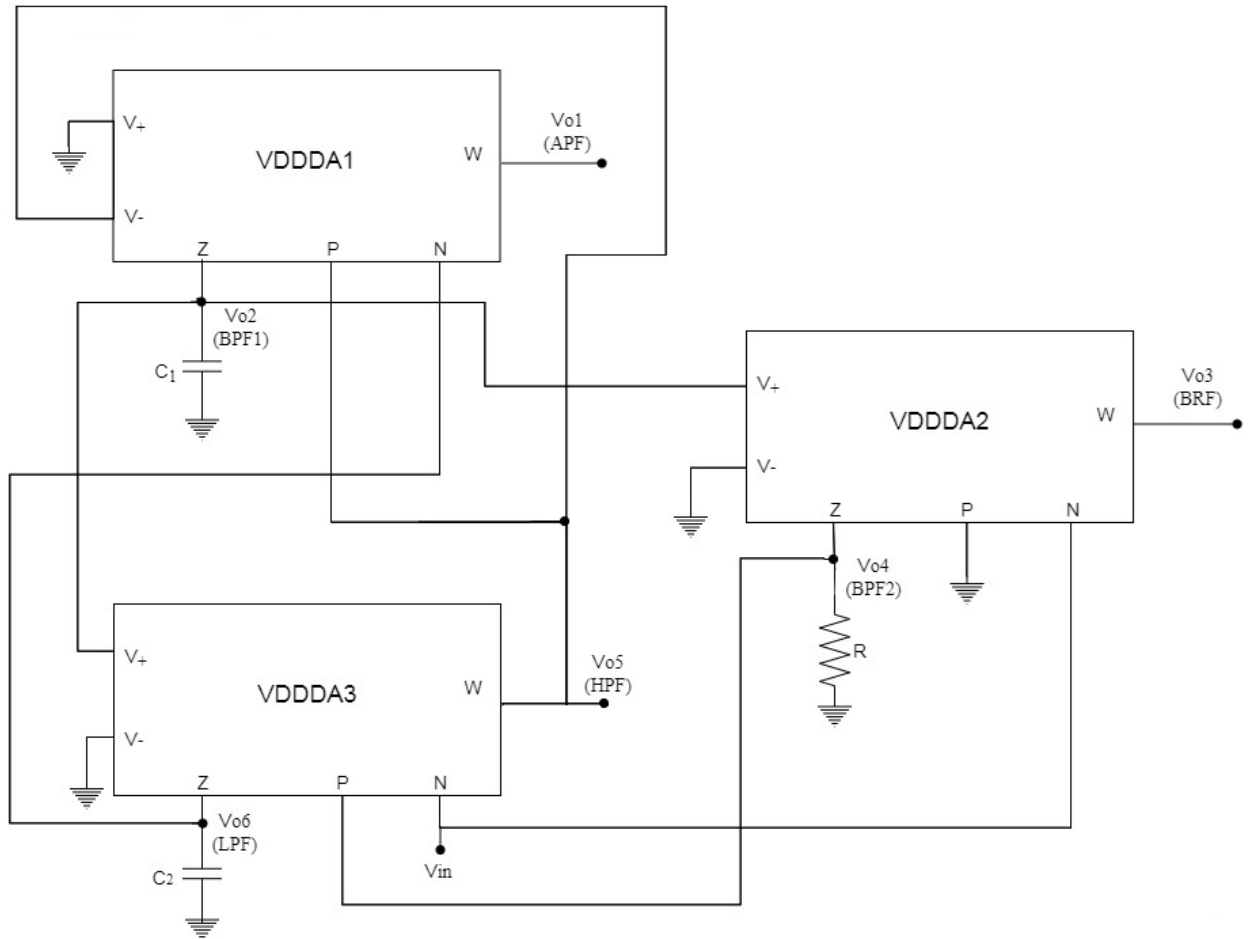


Fig. 5 VDDDA based voltage-mode SIMO filter

The benefits of SIMO filters are (i) we can apprehend low-pass, high-pass, band-pass, band-stop, and all-pass filter responses simultaneously without changing the circuit topology and input signal values, (ii) it plays an important role in the fields of electronic measurement, communication, auto control, and neural network, and (iii) it only requires single input supply voltage for all five filter responses. Fig. 5 shows the proposed voltage-mode universal SIMO filter. The filter consists of three VDDDAs, two grounded capacitors and one grounded resistor. It is worth noting that the proposed filter uses grounded and minimum number of active elements makes this an attractive feature for monolithic integration. It exhibits low output impedance for HP, BR and AP terminals. This proposed universal filter can provide six

filter responses simultaneously which are LP, HP, BR, AP and BP (BP₁ and BP₂) with high input impedance. Considering an ideal VDDDA block, mathematical analysis of the SIMO filter provides the following output responses:

$$HP(s) = \frac{V_{05}}{V_{in}} = -\frac{s^2}{D(s)} \quad (13)$$

$$LP(s) = \frac{V_{06}}{V_{in}} = \frac{\frac{g_{m1}g_{m3}}{C_1C_2}}{D(s)} \quad (14)$$

$$BS(s) = \frac{V_{03}}{V_{in}} = -\frac{s^2 + \frac{g_{m1}g_{m3}}{C_1C_2}}{D(s)} \quad (15)$$

$$AP(s) = \frac{V_{01}}{V_{in}} = -\frac{\left[s^2 - s\frac{g_{m1}}{C_1} + \frac{g_{m1}g_{m3}}{C_1C_2} \right]}{D(s)} \quad (16)$$

$$BP_1(s) = \frac{V_{02}}{V_{in}} = \frac{s\frac{g_{m1}}{C_1}}{D(s)} \quad (17)$$

$$BP_2(s) = \frac{V_{04}}{V_{in}} = \frac{s\frac{g_{m1}g_{m2}R}{C_1}}{D(s)} \quad (18)$$

where,

$$D(s) = s^2 + s\frac{g_{m1}g_{m2}R}{C_1} + \frac{g_{m1}g_{m3}}{C_1C_2} \quad (19)$$

From Eqs (13-19), it is found that all the filter responses have unity gain; it means that if a designer wants to use the filter for a real-time application, there is need of additional voltage amplifier to get some extra gain. Also, the characteristics equation provides the natural frequency and quality factor which are given as below:

$$\omega_0 = \sqrt{\frac{g_{m1}g_{m3}}{C_1C_2}} \quad (20)$$

$$Q_0 = \frac{1}{g_{m2}R} \sqrt{\frac{C_1g_{m3}}{C_2g_{m1}}} \quad (21)$$

It should be noted from Eqs (20) and (21) that the natural frequency (ω_0) can be electronically tuned if g_{m_1} is equal to g_{m_3} , without affecting the quality factor. Also, the quality factor (Q_0) can be electronically tuned independently via g_{m_2} . Thus, both natural frequency and quality factor are orthogonal to each other. However, for realizing AP response, the proposed circuit needs component matching condition ($g_{m_2} = 1/R$).

The relative sensitivities of natural frequency and quality factor for the proposed filter can be calculated in Eq. (22),

$$\begin{aligned} S_{g_{m_1}}^{\omega_0} = S_{g_{m_3}}^{\omega_0} = \frac{1}{2}; \quad S_{C_1}^{\omega_0} = S_{C_2}^{\omega_0} = -\frac{1}{2}; \\ S_{g_{m_2}}^{Q_0} = S_R^{Q_0} = -1; \quad S_{C_1}^{Q_0} = S_{g_{m_3}}^{Q_0} = \frac{1}{2}; \quad S_{C_2}^{Q_0} = S_{g_{m_1}}^{Q_0} = -\frac{1}{2} \end{aligned} \quad (22)$$

3.3.1 Analysis of non-ideal behaviour

Practically, the overall performances of the proposed SIMO filter are affected by the influences of voltage tracking error of VDDDA block. In this section, we will study and analyse these non-ideal characteristics of VDDDA which can be represented as following:

$$V_w = \beta_z V_z - \beta_n V_n + \beta_p V_p \quad (23)$$

“where in Eq. (23), β_z , β_n and β_p represent the non-ideal voltage gain (or, voltage tracking error) of VDDDA from Z, N and P ports to W port, respectively and it is less than one in magnitude. For ideal case, β is taken as unity gain.” The voltage filter responses for the non-ideal case are represented in Eqs (24-29):

$$LP^*(s) = \frac{V_{06}}{V_{in}} = \frac{g_{m_1} g_{m_3} \beta_{n3}}{C_1 C_2 D(s)} \quad (24)$$

$$HP^*(s) = \frac{V_{05}}{V_{in}} = -\frac{s^2 \beta_{n3}}{D(s)} \quad (25)$$

$$BS^*(s) = \frac{V_{03}}{V_{in}} = \frac{-\left[s^2\beta_{n2} + s\frac{g_{m1}g_{m2}R}{C_1}(\beta_{n2}\beta_{p3} - \beta_{z2}\beta_{n3}) + \frac{g_{m1}g_{m3}\beta_{n2}\beta_{z3}}{C_1C_2}\right]}{D(s)} \quad (26)$$

$$AP^*(s) = \frac{V_{01}}{V_{in}} = -\frac{\left(s^2\beta_{p1}\beta_{n3} - s\frac{g_{m1}\beta_{z1}\beta_{n3}}{C_1} + \frac{g_{m1}g_{m3}\beta_{n1}\beta_{n3}}{C_1C_2}\right)}{D(s)} \quad (27)$$

$$BP_1^*(s) = \frac{V_{02}}{V_{in}} = \frac{s\frac{g_{m1}\beta_{n3}}{C_1}}{D(s)} \quad (28)$$

$$BP_2^*(s) = \frac{V_{04}}{V_{in}} = \frac{s\frac{g_{m1}g_{m2}R\beta_{n3}}{C_1}}{D(s)} \quad (29)$$

where,

$$D^*(s) = s^2 + s\frac{g_{m1}g_{m2}R\beta_{p3}}{C_1} + \frac{g_{m1}g_{m3}\beta_{z3}}{C_1C_2} \quad (30)$$

From Eq. (30), it is noted that the tracking error will also affect the natural frequency and the quality factor of the proposed filter. The non-ideal values of ω_0 and Q_0 are given below,

$$\omega_0^* = \sqrt{\frac{g_{m1}g_{m3}\beta_{n3}}{C_1C_2}} \quad (31)$$

$$Q_0^* = \frac{1}{g_{m2}R\beta_{p3}} \sqrt{\frac{C_1g_{m3}\beta_{n3}}{C_2g_{m1}}} \quad (32)$$

CHAPTER 4

SIMULATION RESULTS

The theoretical study of CMOS implemented VDDDA structure in Fig. 3 and the proposed filters as shown in Fig. 4 and 5, have been verified by SYMICA DE simulations. The transistors in the circuit design are modelled by the TSMC 0.18 μm level-7 CMOS process parameters ($V_{\text{THn}} = 0.3725 \text{ V}$, $\mu_n = 259.5304 \text{ cm}^2/(\text{V}\cdot\text{s})$, $V_{\text{THp}} = -0.3948 \text{ V}$, $\mu_p = 109.9762 \text{ cm}^2/(\text{V}\cdot\text{s})$, $T_{\text{ox}} = 4.1 \text{ nm}$) [60] with $\pm 0.9 \text{ V}$ supply voltages and $V_B = -0.35 \text{ V}$. From Table 4, aspect ratio of MOS transistors are listed.

The functionality of CMOS implemented VDDDA is shown in Fig. 6 which is verified through SYMICA DE simulation using 0.18 μm TSMC CMOS parameter.

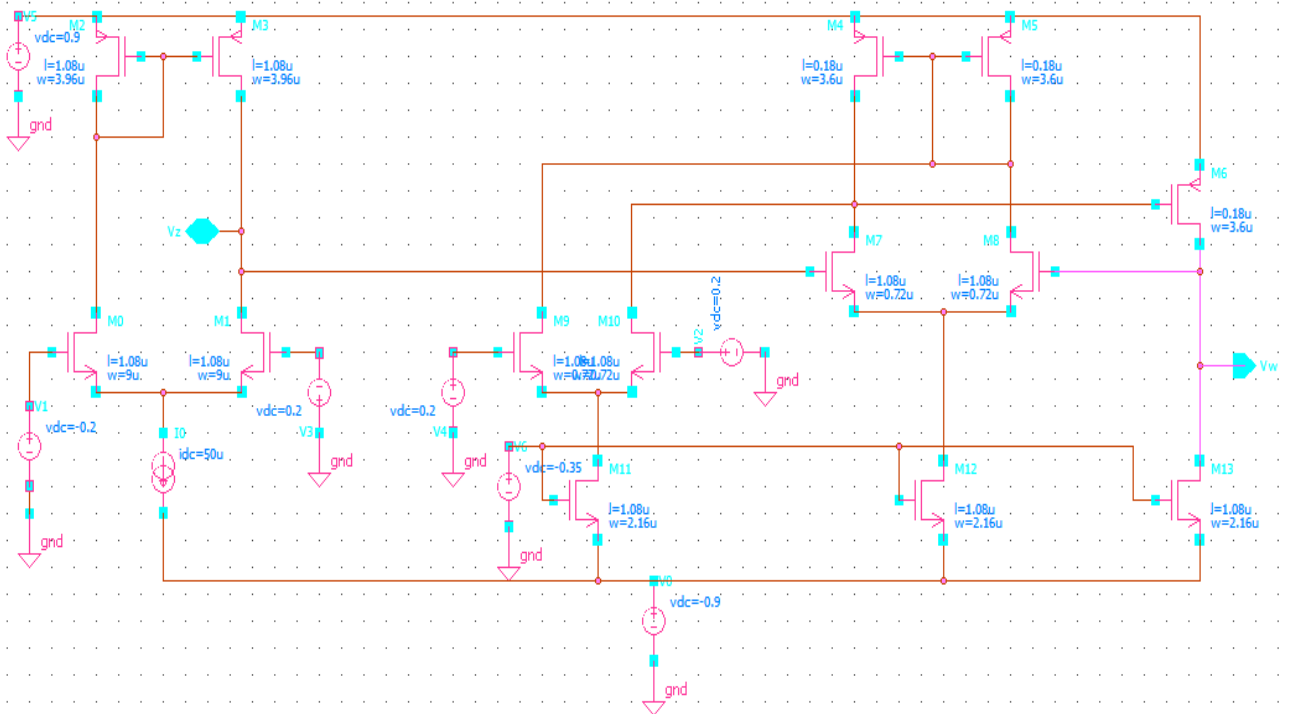


Fig. 6 Schematic of CMOS implemented VDDDA

Table 4 Aspect ratios of MOS transistors [5]

NMOS transistors	W(μm) / L(μm)
M ₁ , M ₂	9/1.08
M ₈ – M ₁₁	0.72/1.08
M ₁₂ – M ₁₄	2.16/1.08
PMOS transistors	W(μm) / L(μm)
M ₃ , M ₄	3.96/1.08
M ₅ – M ₇	3.6/0.18

4.1 Analyses of VDDDA

The performance of the VDDDA was tested and depicted in Figs. 7 to 11 in which relations between the output and input terminals are verified. From the DC analyses, it is noted that the input voltage terminals have maximum voltage equal to ± 200 mV. The bias current is selected as $I_B = 50 \mu\text{A}$, which results in g_m approximately equal to $300 \mu\text{A/V}$. Subsequently, the obtained gains β_i of voltage transfers $V_w / \{V_z, V_n, V_p\}$ are equal to 0.997.

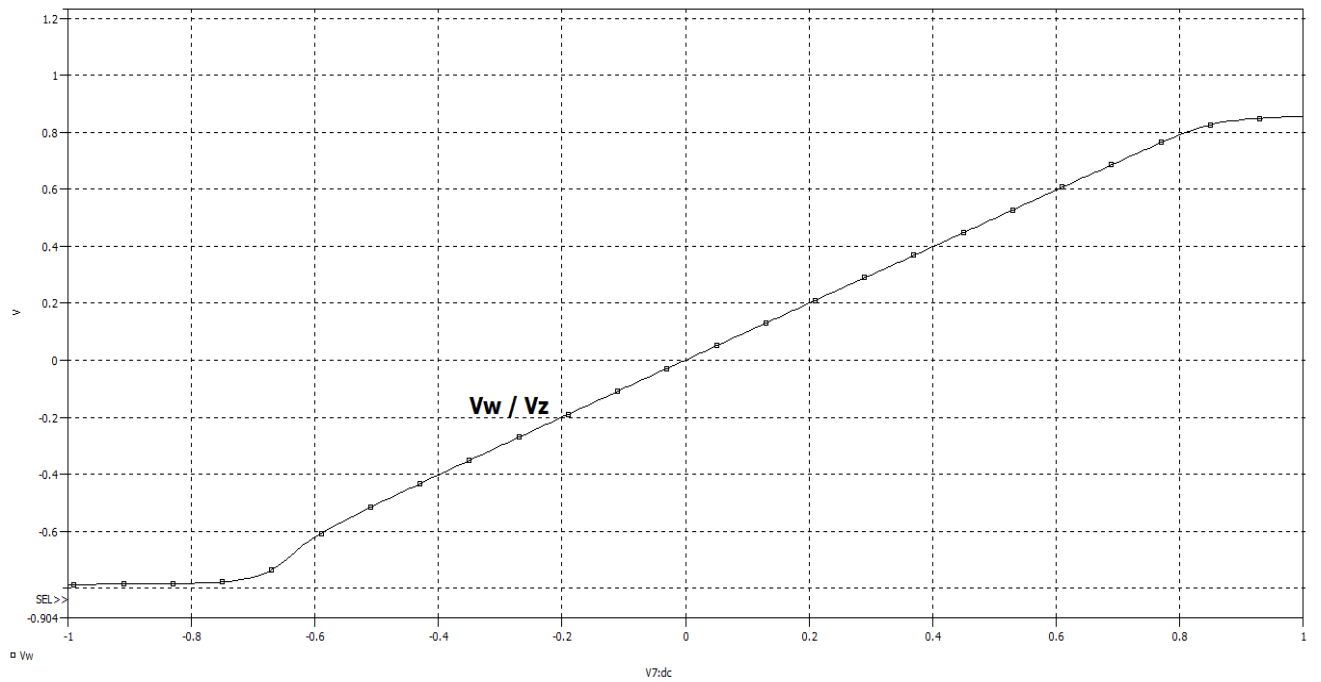


Fig. 7 DC analysis of VDDDA (V_w vs V_z)

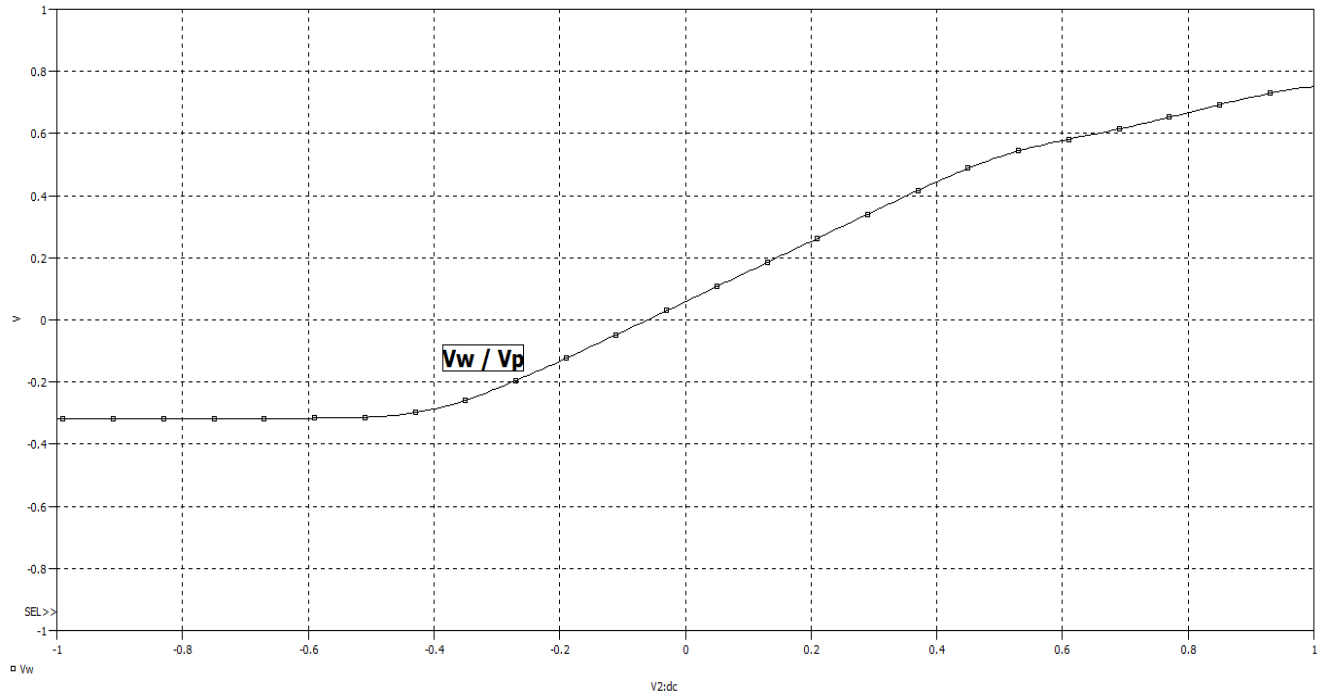


Fig. 8 DC analysis of VDDDA (V_w vs V_p)

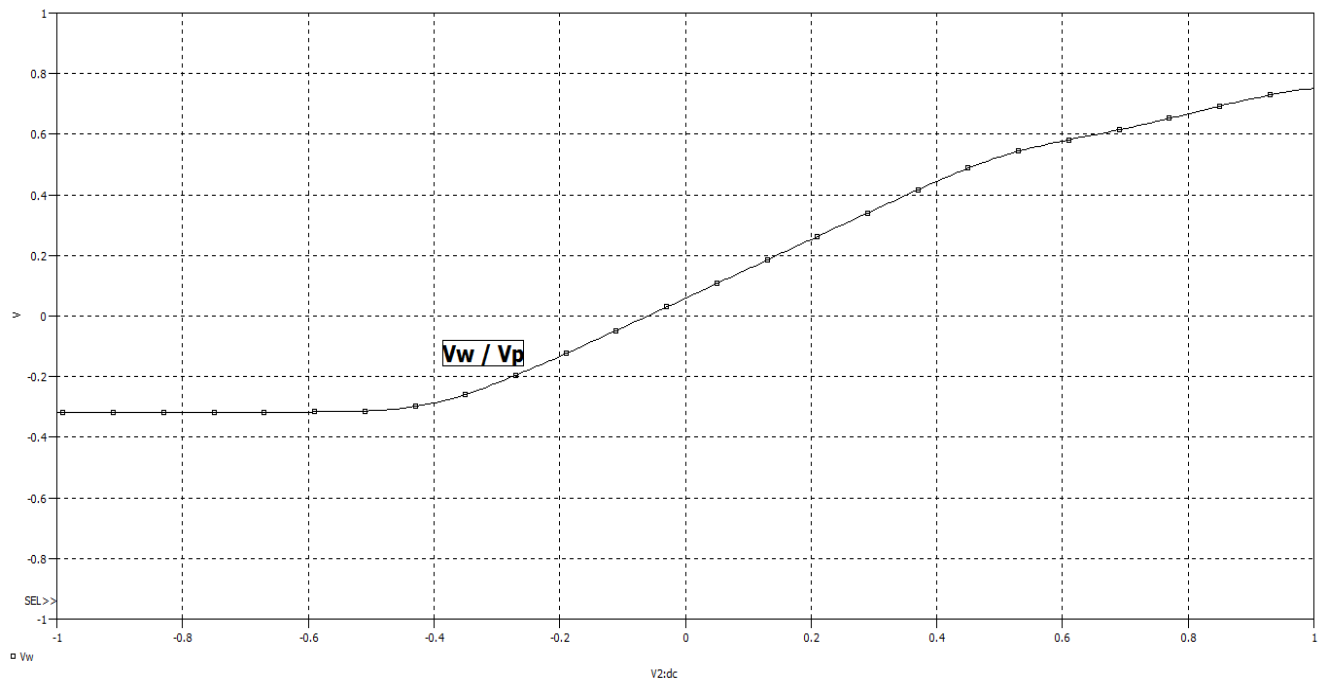


Fig. 9 DC analysis of VDDDA (V_w vs V_n)

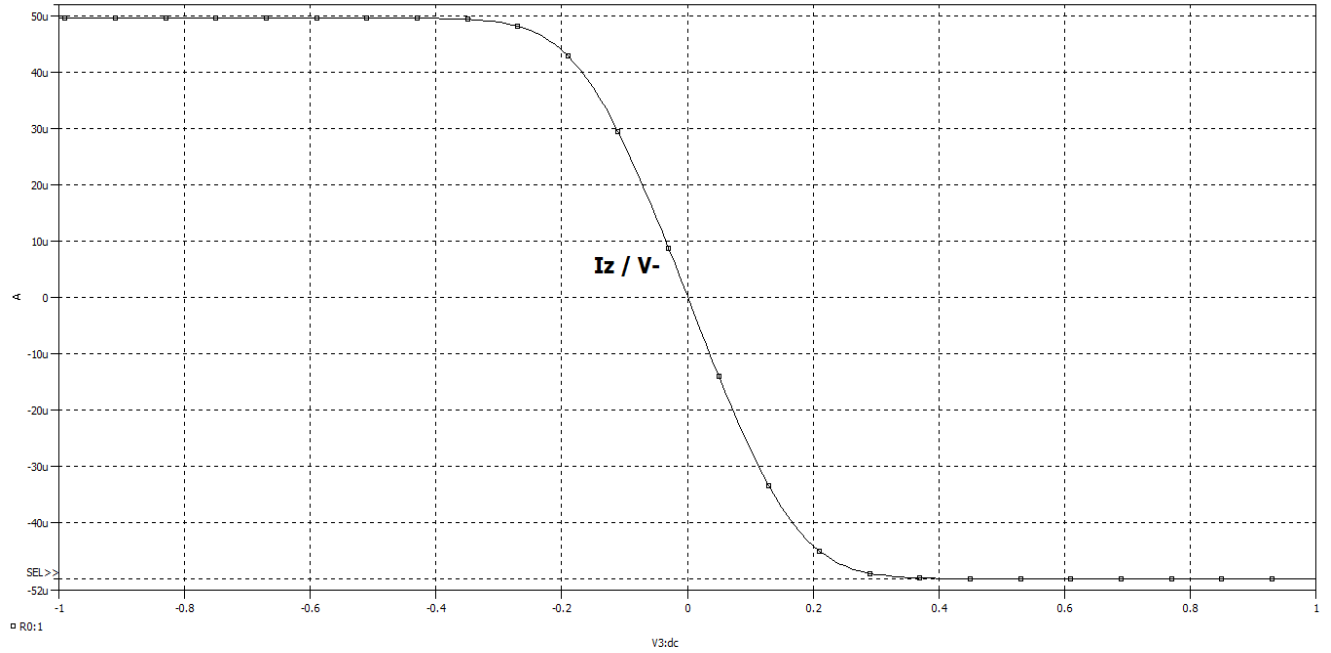


Fig. 10 DC analysis of VDDDA (I_z vs V_-)

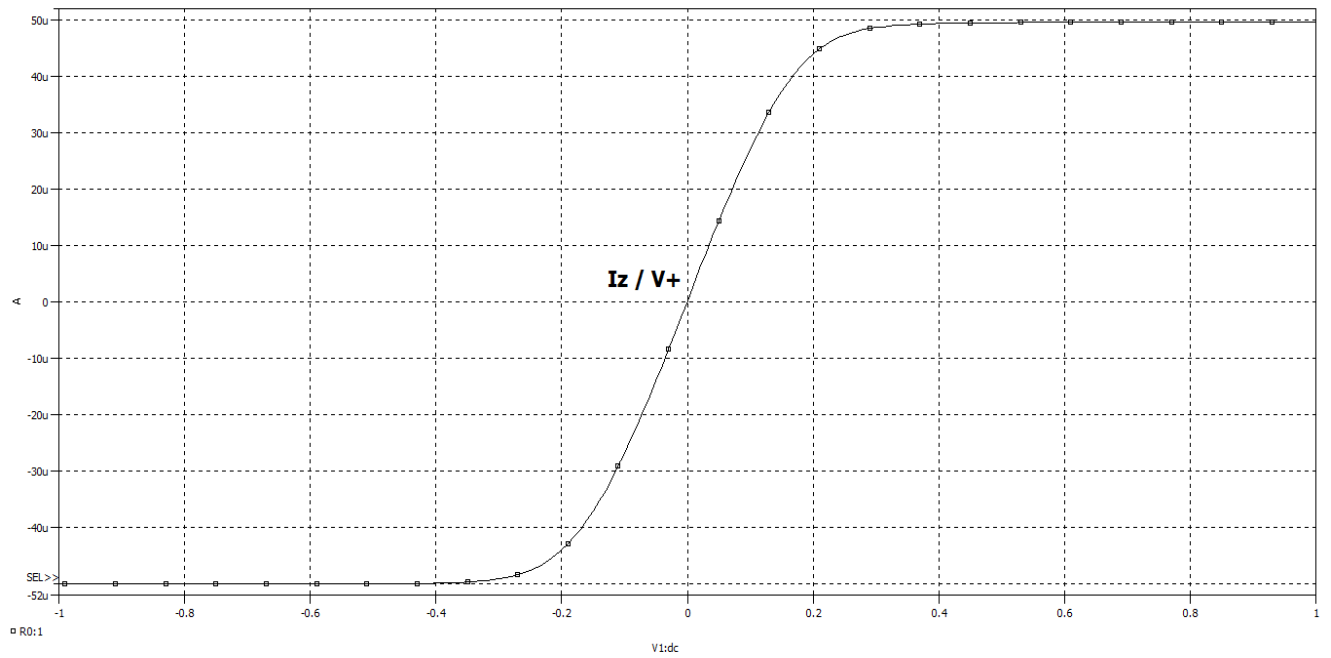


Fig. 11 DC analysis of VDDDA (I_z vs V_+)

From Eq. (6) we can see that V_w is proportional to V_p and V_n for an ideal VDDDA, i.e. $\beta_i = 1$ and above graphs show their dependence on input voltages.

4.2 Analyses of Proposed VM MISO filter

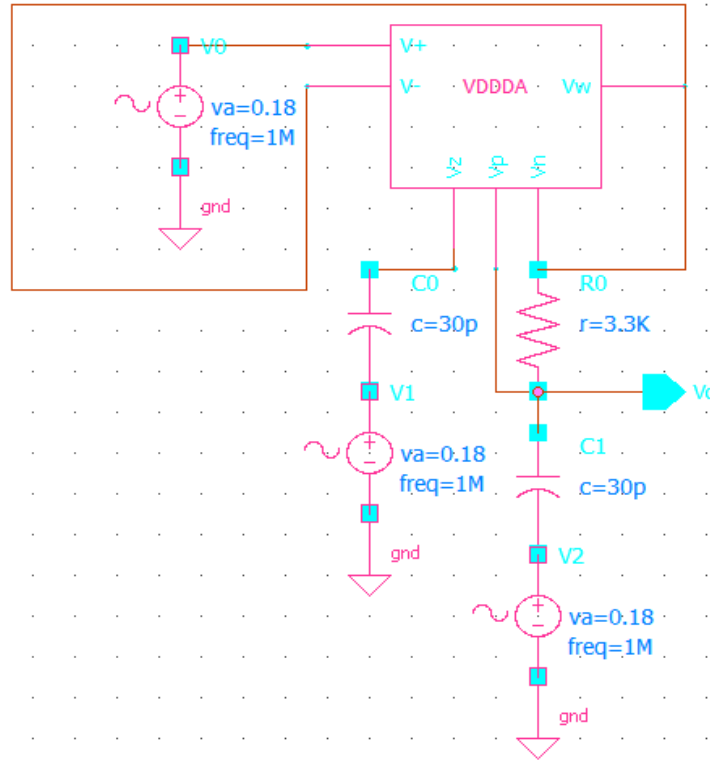


Fig. 12 Schematic of proposed MISO filter using VDDDA

The functionality of CMOS implemented proposed multifunction MISO filter as shown in Fig. 12, is verified through SYMICA DE simulations with model library of 0.18 μm TSMC CMOS parameter file [60] at $\pm 0.9\text{V}$ supply voltages. The aspect ratio of the transistors is tabulated in Table 4. The component's values used in filter are as follows: $C_1 = C_2 = 30 \text{ pF}$ and $R = 3.3\text{k}\Omega$ and the bias current I_B is set to $50 \mu\text{A}$. Figs. (13-15) provide the gain responses of LP, HP and BP functions and Fig. 16 and 17 provide the gain and phase responses of BS and AP functions of the proposed MISO filter. The simulated natural frequency is 1.106 MHz and the quality factor is 0.707. But the theoretical natural frequency in Eq. (10) is 1.131 MHz with the same value of passive components and bias current. This deviation is due to voltage tracking error or non-ideal nature of VDDDA. The transient response of BP function is shown in Fig. 18. In this experiment, the input is a sinusoidal signal with 180 mV and 1 MHz frequency was fed into the proposed filter.

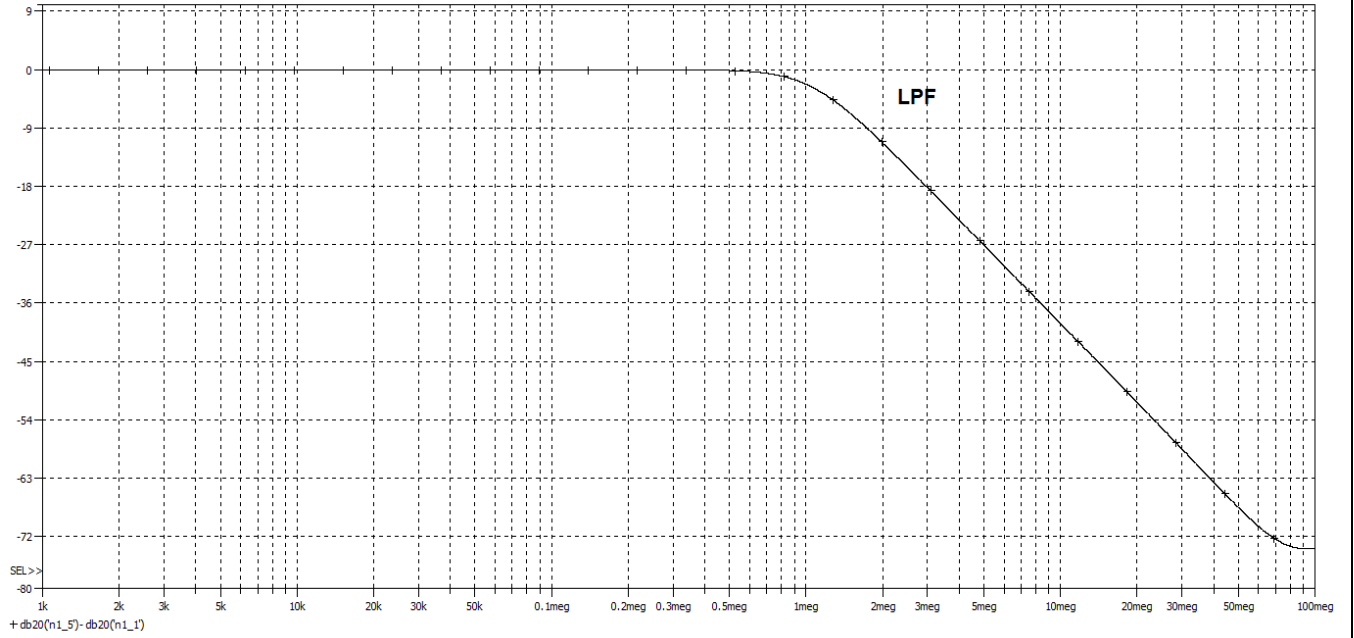


Fig. 13 Gain response of LP

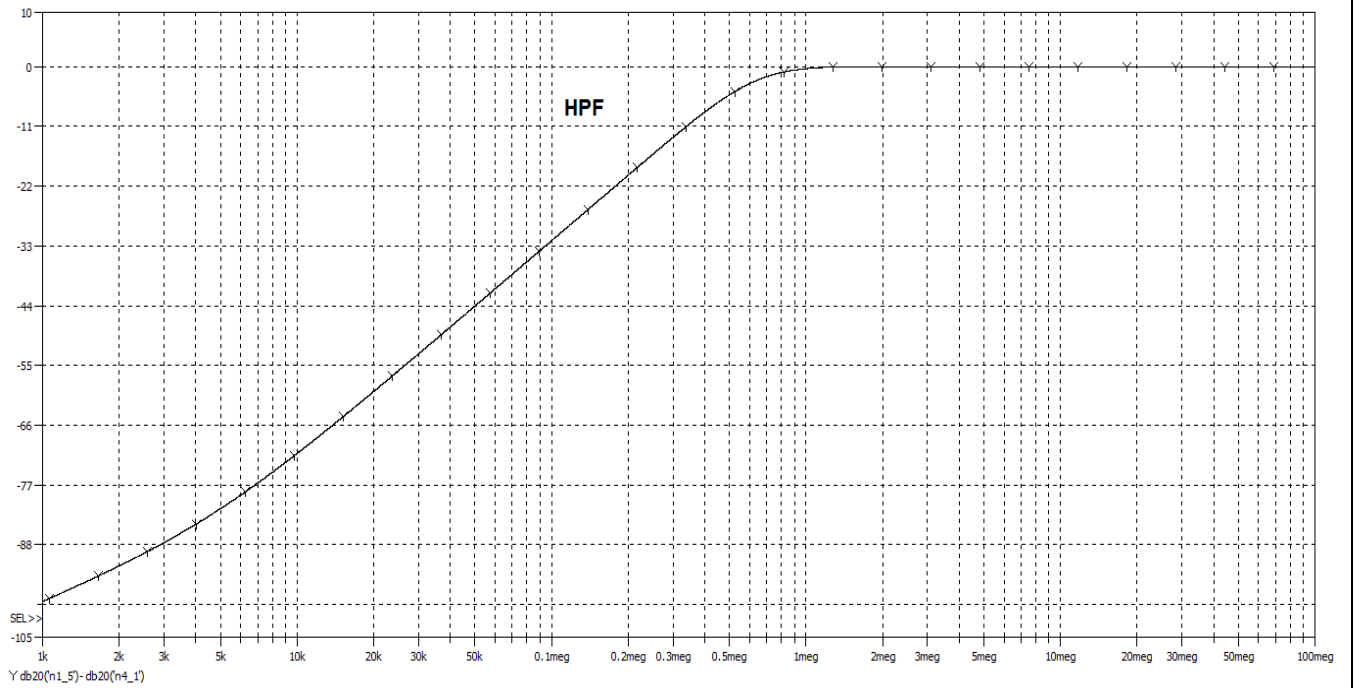


Fig. 14 Gain response of HP

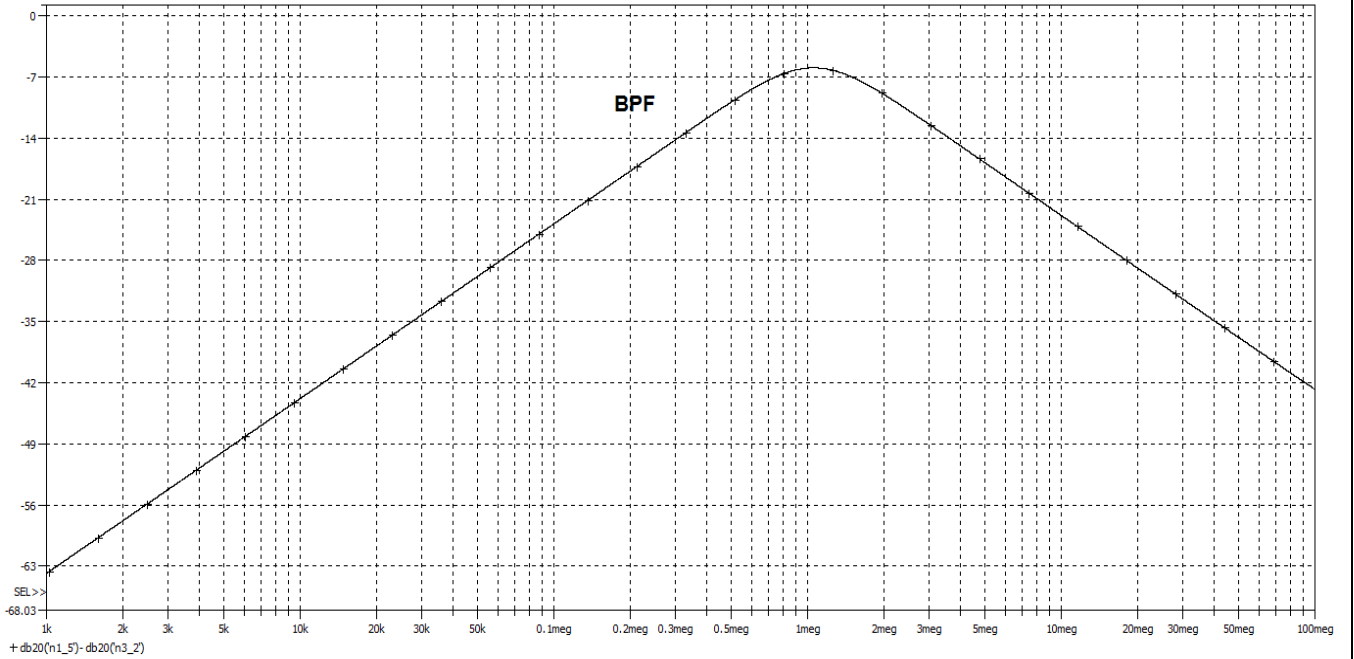


Fig. 15 Gain response of BP

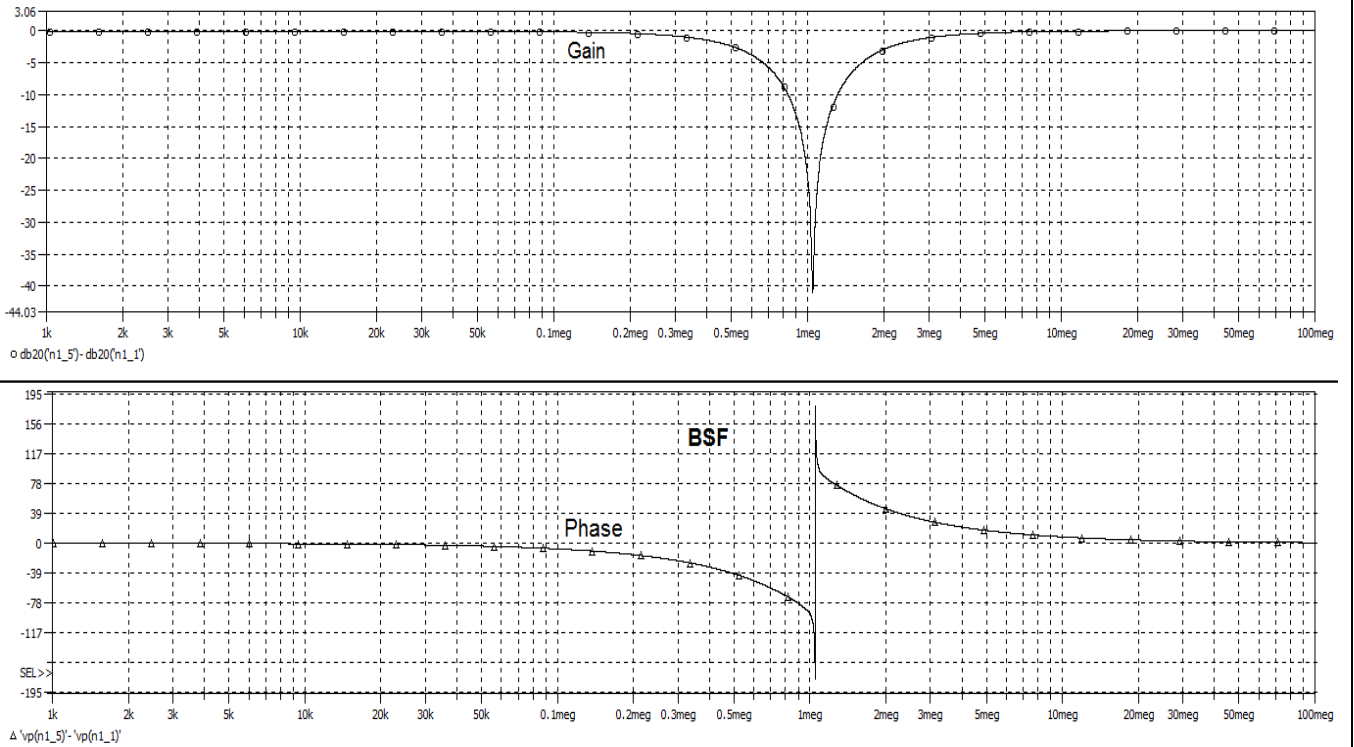


Fig. 16 Gain and phase response of BS

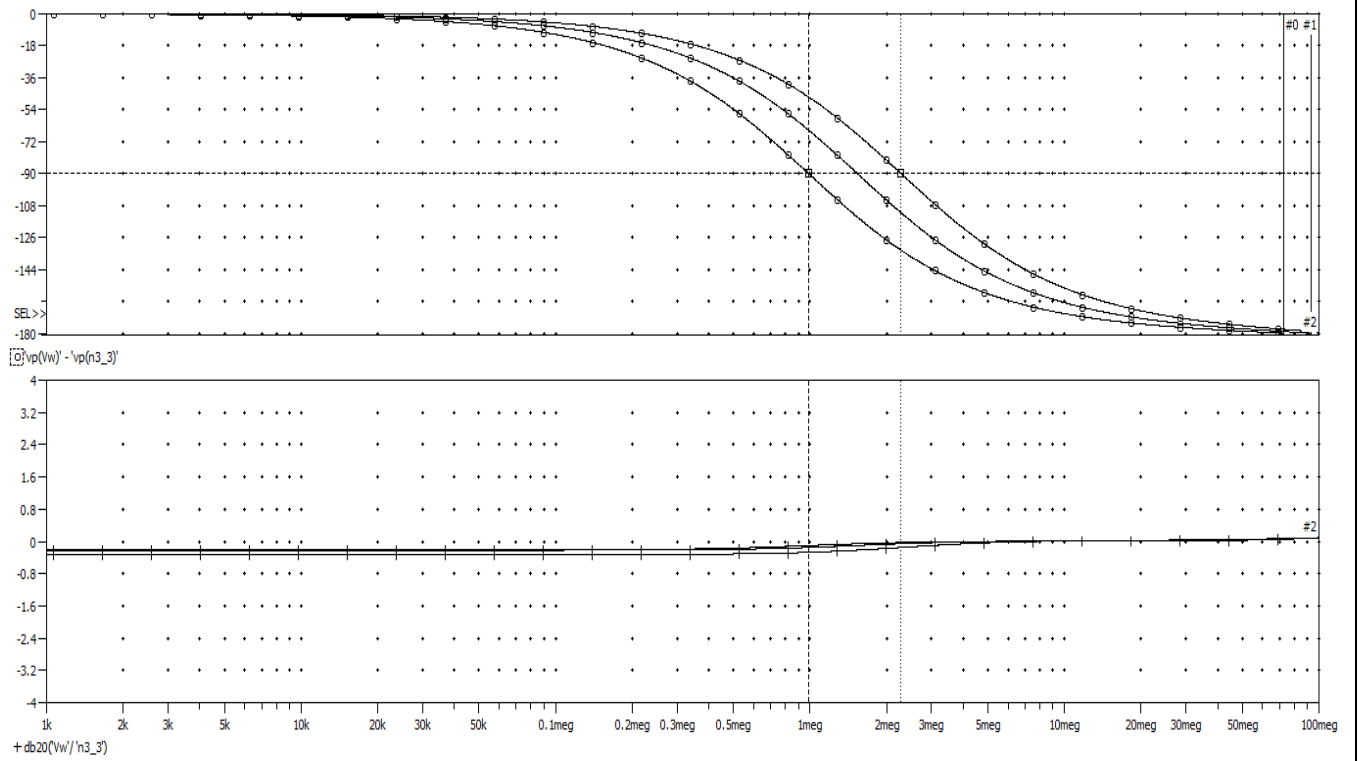


Fig. 17 Gain and phase response of AP

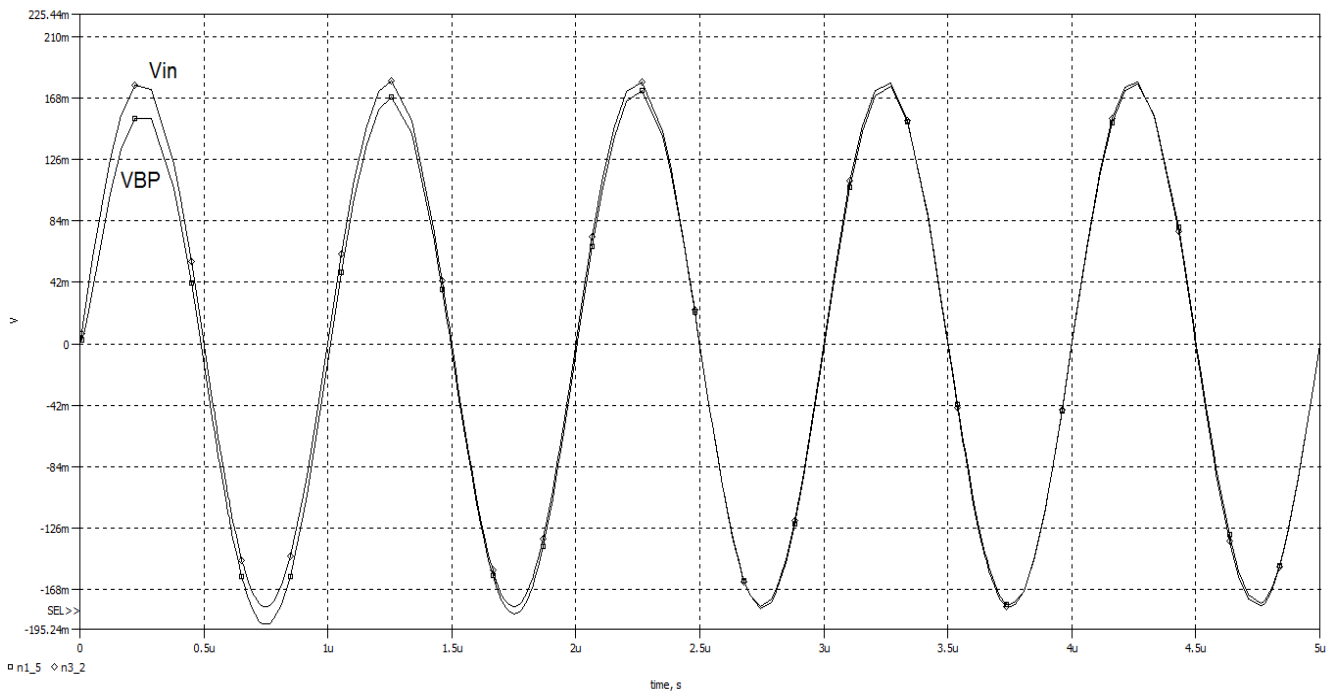


Fig. 18 Transient response of BP function

The gain responses of BP function for different I_B are shown in Fig. 19, where $C_1 = C_2 = 30$ pF and I_B is equal to $50 \mu\text{A}$, $100 \mu\text{A}$ & $150 \mu\text{A}$ and the corresponding simulated natural frequencies are 1.106 MHz, 1.272 MHz and 1.355 MHz respectively. This is confirmed from Eq. (10) and (11) that the natural frequency can be electronically tuned via I_B .

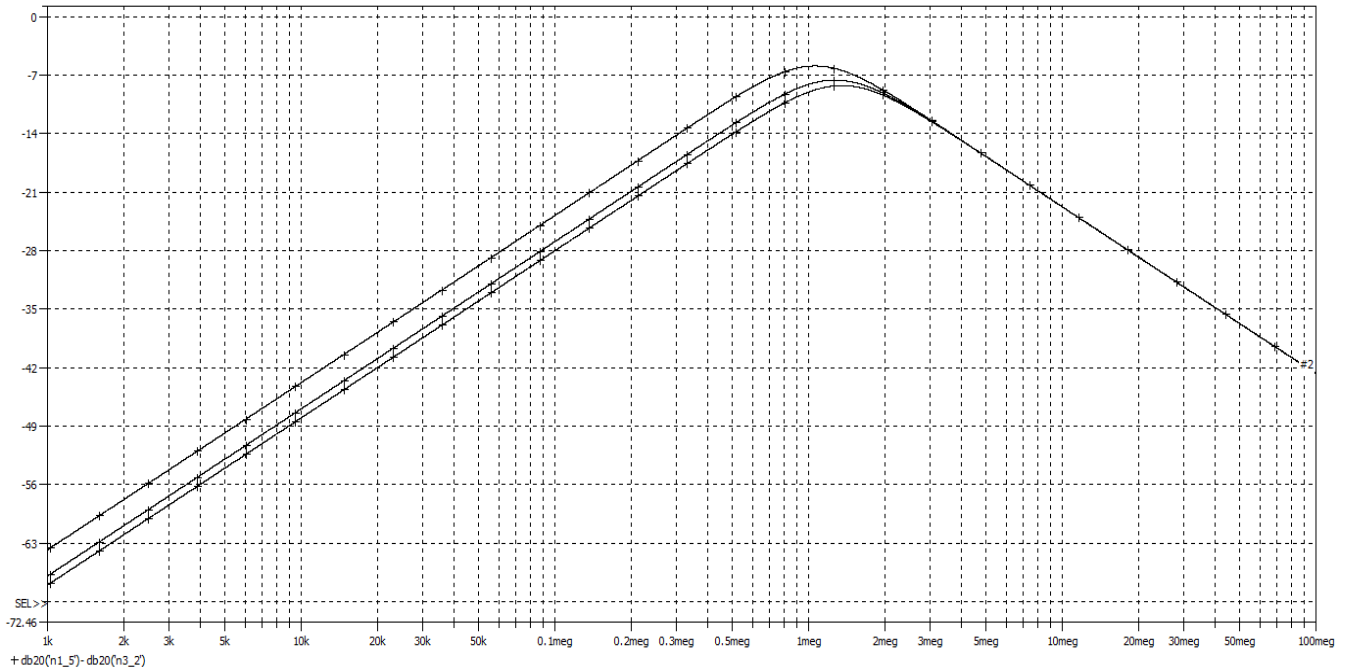


Fig. 19 BP responses for different values of I_B

4.3 Analyses of Proposed VM SIMO Universal filter

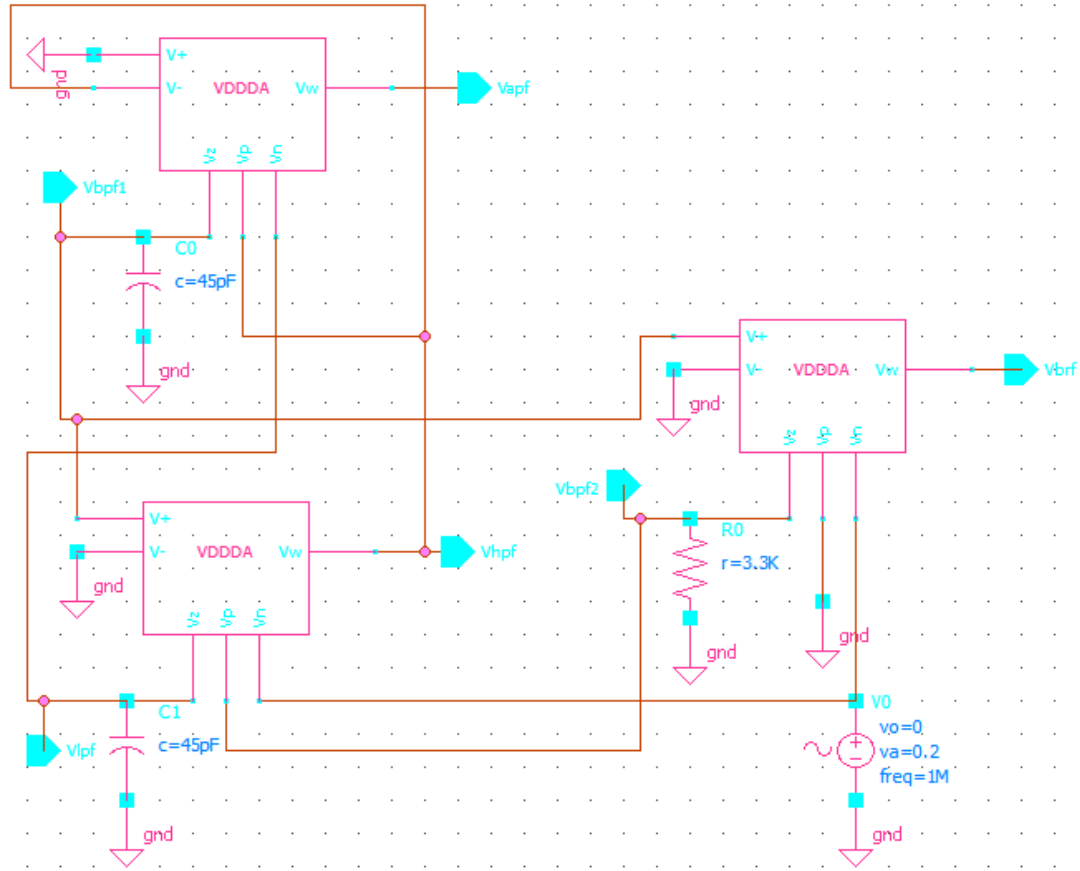


Fig. 20 Schematic of proposed SIMO filter using VDDDA

The functionality of CMOS implemented proposed universal SIMO filter as shown in Fig. 20, is verified through SYMICA DE simulations with model library of 0.18 μm TSMC CMOS parameter file [60] at $\pm 0.9\text{V}$ supply voltages. The aspect ratios of MOS transistors are listed in Table 4. The values of the components used in filter are as follows: $C_1 = C_2 = 45 \text{ pF}$, $R = 3.3\text{k}\Omega$ and $I_{B1} = I_{B2} = I_{B3} = 50 \mu\text{A}$. Figs. (21-24) provide the gain responses of LP, HP, BP₁ and BP₂ functions and Fig. 25 and 26 provide the gain and phase responses of BR and AP functions of the proposed SIMO filter respectively. The simulated natural frequency is 1.023 MHz and the quality factor is unity. But the theoretical natural frequency in Eq. (20) is 1.061 MHz with the same value of passive components and bias current. This deviation is due to the voltage tracking error or non-ideal nature of VDDDA. The proposed circuit is a universal filter means that it can simultaneously provide low-pass, high-pass, band-pass, band-reject/notch and

all-pass functions without switching the circuit topology. The gain responses of BP₂ function for different I_{B2} are shown in Fig. 27, where C₁ = C₂ = 45 pF and I_{B2} is equal to 25 μA, 50 μA & 100 μA and the corresponding values of quality factor (Q₀) are 1.414, 1 and 0.707 respectively. It is confirmed from Eq. (21) that the quality factor can be electronically tuned via g_{m2} by changing I_{B2} without altering natural frequency. To get high Q₀, we can set the value of I_{B2} as low as possible.

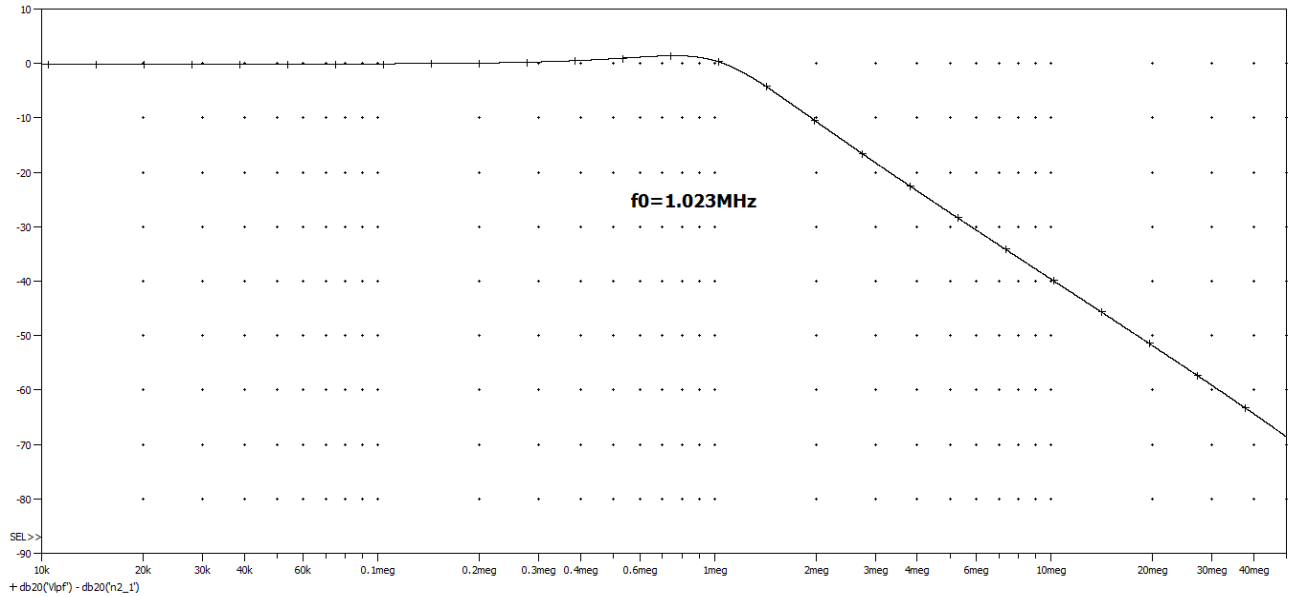


Fig. 21 Gain response of LP

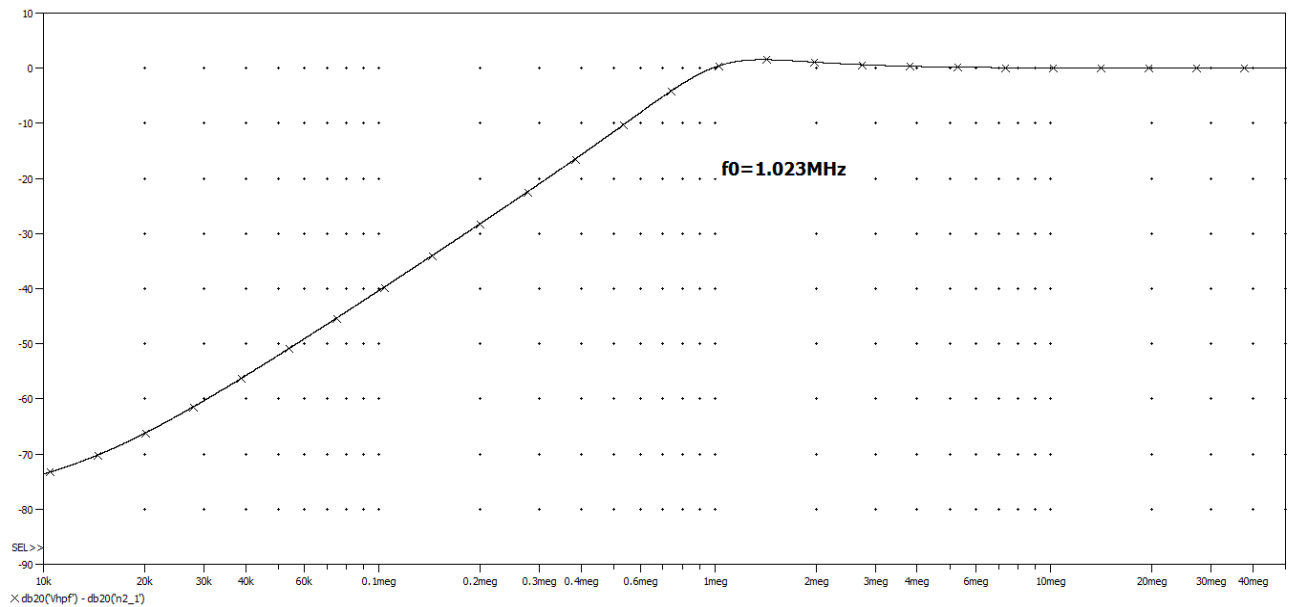


Fig. 22 Gain response of HP

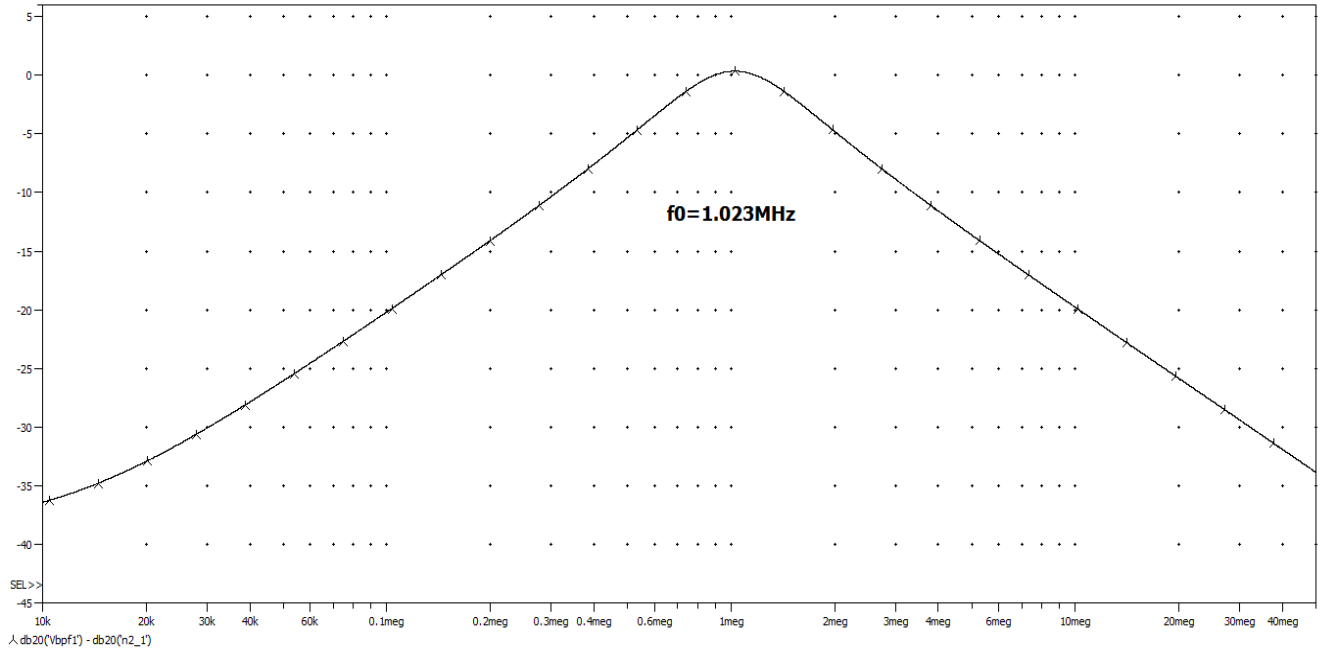


Fig. 23 Gain response of BP₁

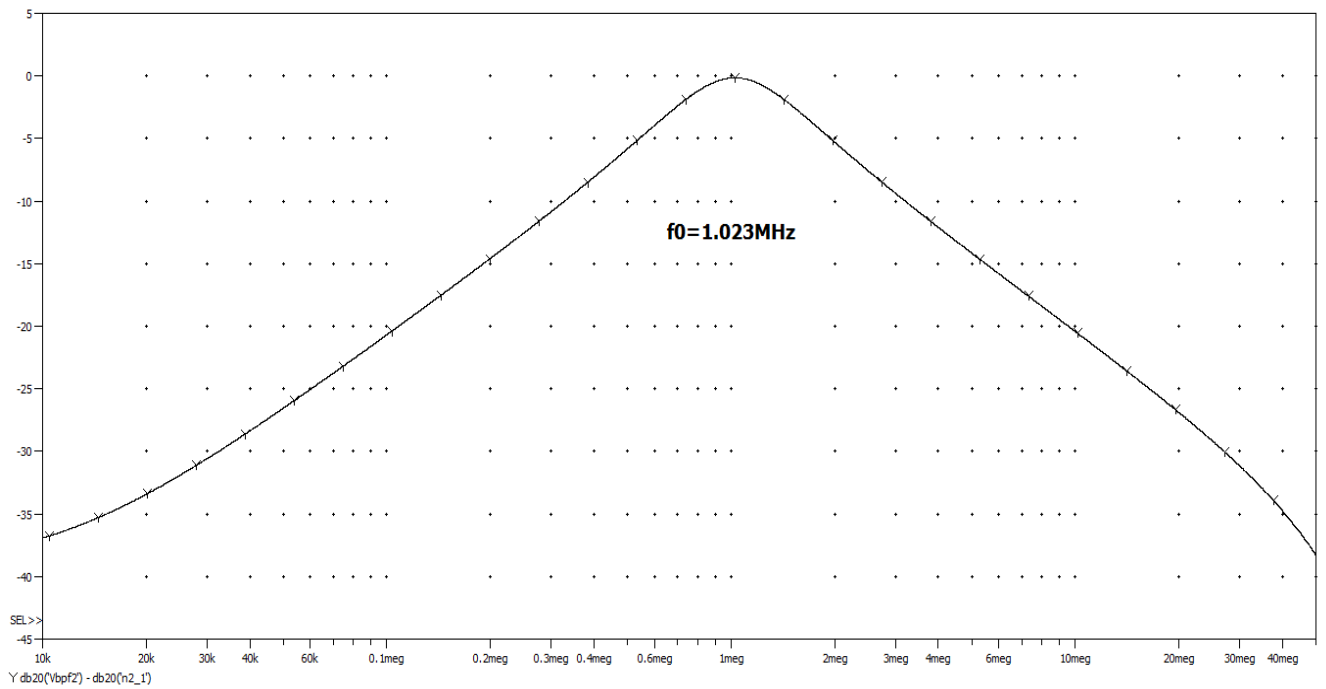


Fig. 24 Gain response of BP₂

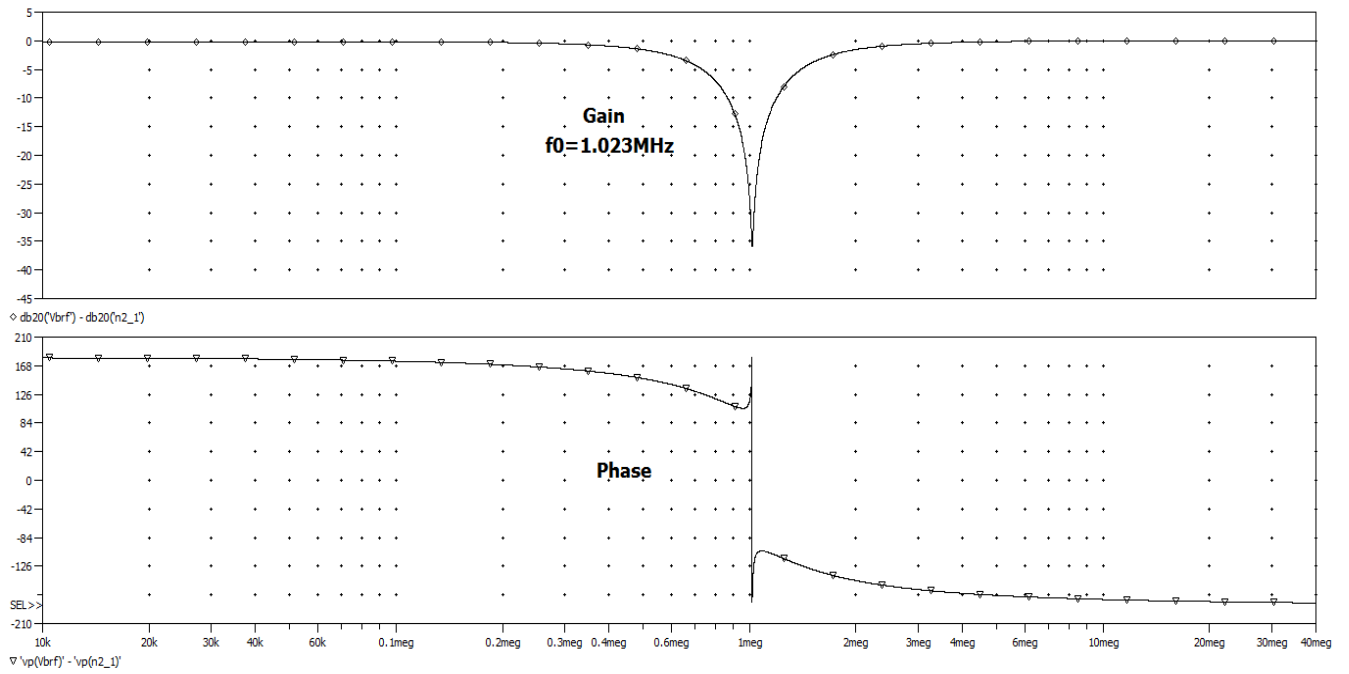


Fig. 25 Gain and phase response of BR

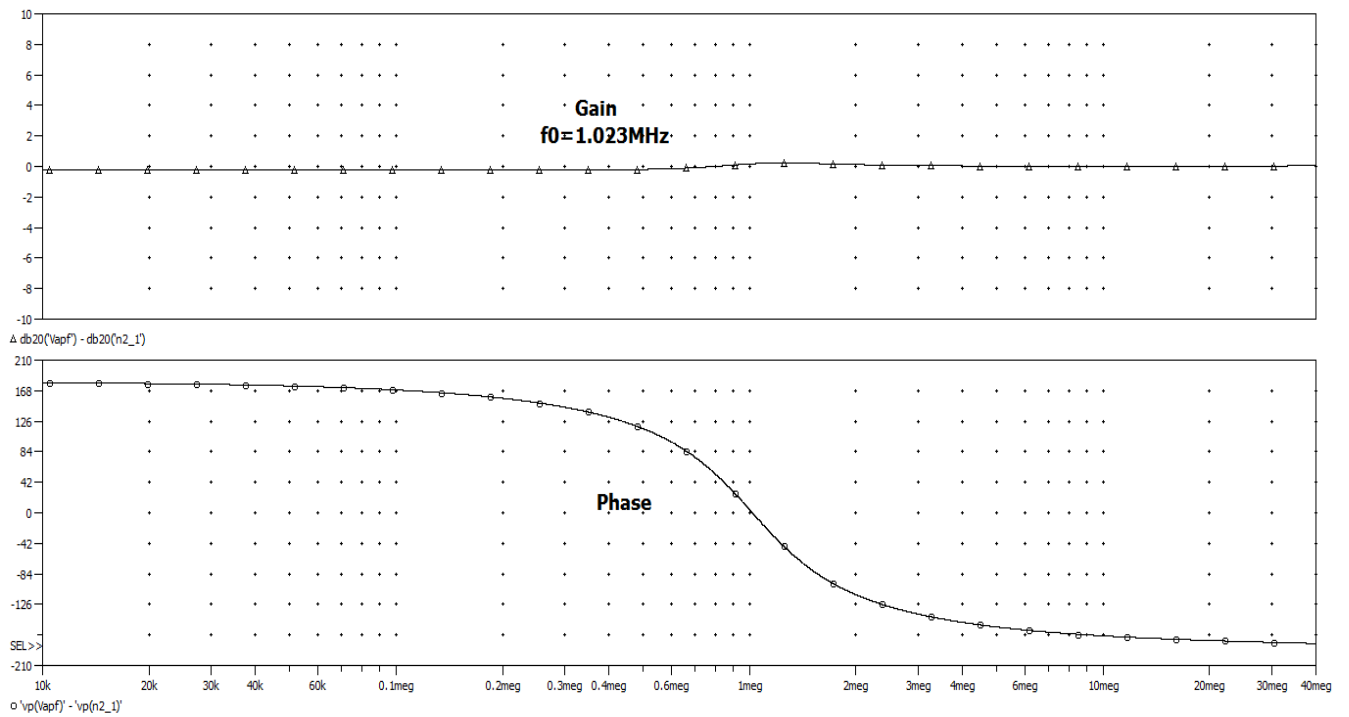


Fig. 26 Gain and phase response of AP

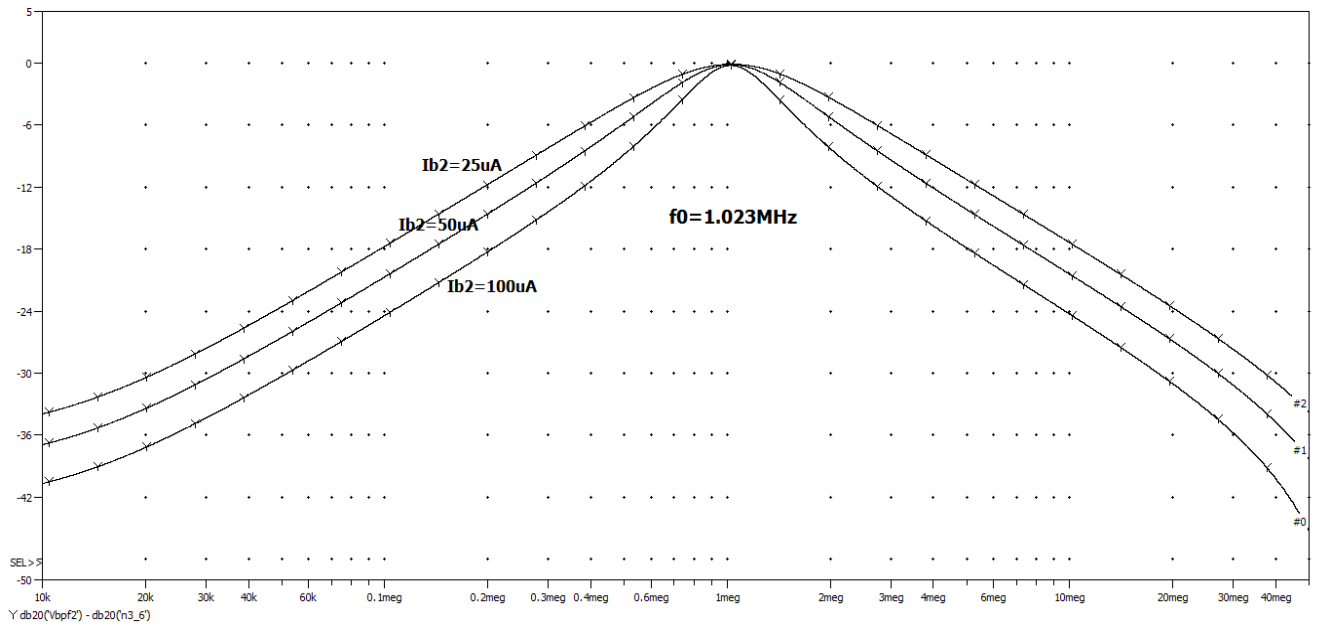


Fig. 27 BP₂ responses for different values of I_{B2}

In order to control the natural frequency (ω_0) without affecting the Q_0 , we can adjust C_1 and C_2 simultaneously. The BP₂ gain responses in Fig.28, by varying $C_1 = C_2$ with different values of capacitance 35 pF, 45 pF and 55 pF. The simulated natural frequencies are 0.825 MHz, 1.023 MHz and 1.289 MHz, respectively.

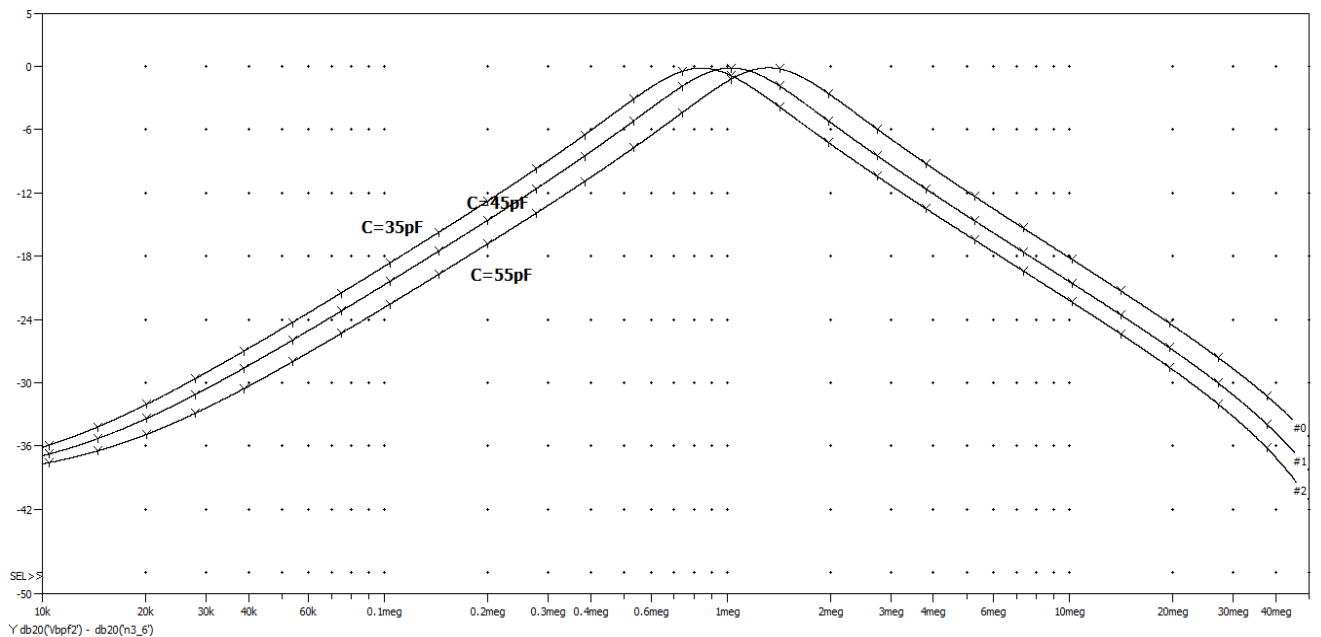


Fig. 28 BP₂ responses for different values of C_1, C_2

The transient response of BP₂ function is shown in Fig. 29. In this experiment, the input is a sinusoidal signal with amplitude of 180 mV and 1 MHz frequency was fed into the proposed filter.

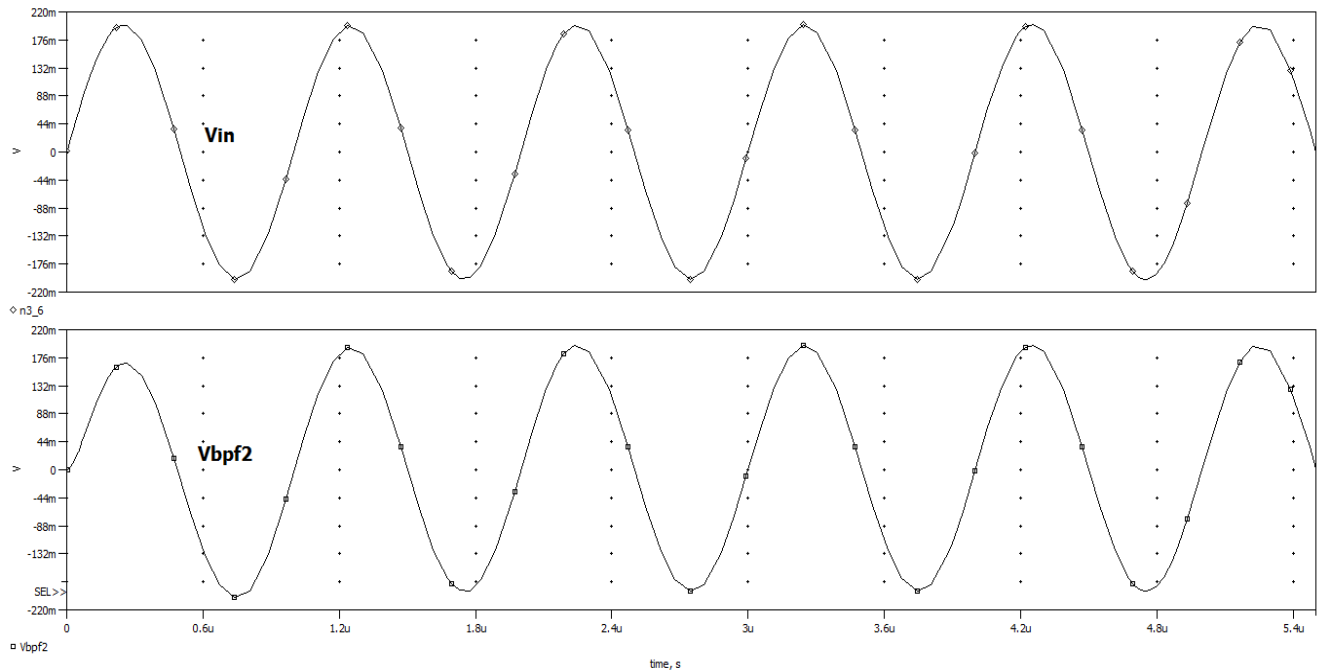


Fig. 29 Transient response of BP₂

CHAPTER 5

CONCLUSION AND FUTURE SCOPE

In this report, two voltage-mode second order filters using VDDDA as an active building block have been proposed along with the study of the VDDDA block. First is a voltage-mode multifunction filter with MISO configuration and the other is voltage-mode Universal filter with SIMO type circuit topology. Following are the advantages of proposed MISO filter: (i) The proposed filter can provide all five standard functions: Low-Pass (LP), High-Pass (HP), Band-Pass (BP), Band-Stop (BS) and All-Pass (AP) responses with digitally terminal switching of input ports, (ii) the natural frequency and the quality factor both can be electronically controllable and tuneable, (iii) it consists of single VDDDA, two capacitors and one resistor and (iv) the input voltage terminal for V_{in1} is high impedance.

The advantages of proposed SIMO filter are as follows: Firstly, the filter circuit consists of three VDDDA, two grounded capacitors and one grounded resistor which is an attractive feature for IC implementation. Secondly, it can realize low-pass, high-pass, band-pass, band-stop, and all-pass filter responses simultaneously without changing circuit topology. Thirdly, it has high input impedance and exhibits low output impedance for HP, BR and AP terminals. Finally, the natural frequency and the quality factor both are electronically and orthogonally controllable and tuneable. Simulation results verified the theoretical concepts and validity of synthesis. However, with slight modification in future, both MISO and SIMO filter can be used for the implementation of the voltage-mode quadrature oscillator, VDDDA based voltage-mode shadow filter and many more applications.

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